# TPSM8281x 2.75V to 6V Input, 1A to 4A Step-Down Power Module With Integrated Inductor and Frequency Synchronization in MicroSiP™ and MagPack™ Package

1 Features

- Adjustable and synchronizable switching frequency of 1.8MHz to 4MHz
- Two package types available
  - MagPack package (shields inductor and IC) 13-pin, < 2.0mm tall
  - µSIL 14-pin, < 2.4mm tall
- Optimized for low EMI requirements
  - Flip-chip die mount (no bond wires)
  - Simplified layout through optimized pinout
- Spread spectrum clocking versions available
- Selectable forced PWM or PFM/PWM operation
- Output voltage accuracy ±1% (PWM operation)
- 2.75V to 6V input voltage range
- 0.6V to 5.5V output voltage range
- Adjustable soft start or tracking
- Power-good output with window comparator
- Precise ENABLE input allows
  - User-defined undervoltage lockout
  - Exact sequencing
- 100% duty cycle
- Output discharge
- 15µA typical quiescent current
- Excellent thermal performance
- –40°C to 125°C operating temperature range
- Pin-to-pin 6A version, 1.6mm tall: TPSM82816
- Create a custom design using the TPSM8281x with the WEBENCH® Power Designer

2 Applications

- Optical modules, data center interconnect
- Test and Measurement
- Patient monitoring and diagnostics
- Wireless infrastructure
- Aerospace and Defense
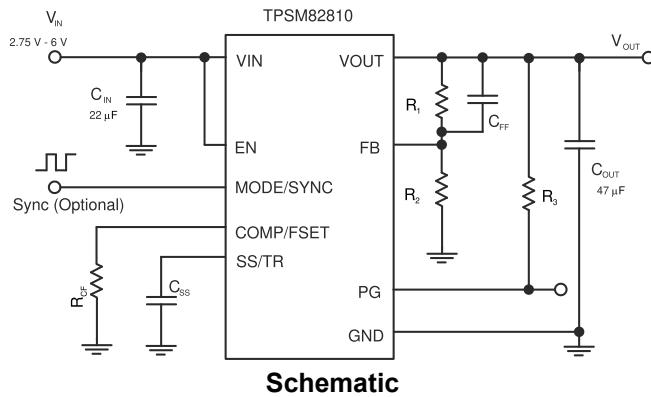
3 Description

TPSM8281x is a family of pin-to-pin compatible, high-efficiency, and easy to use synchronous step-down DC/DC power modules with integrated inductors with output currents ranging from 1A up to 4A. The devices use a fixed-frequency peak current-mode control topology and support high power density requirements for telecommunication, test and measurement, and medical applications. Low resistance switches allow up to 4A continuous output current at high ambient temperatures. The switching frequency is adjustable from 1.8MHz to 4MHz and can also be synchronized to an external clock. In PFM/PWM mode, the TPSM8281x maintains high efficiency over the whole load range. The devices provide 1% output voltage accuracy in PWM mode, which eases designing precise power supplies. The SS/TR pin can be used to limit inrush current through a precise start-up ramp, or for sequencing by tracking the output voltage to an external voltage applied to this pin.

Device Information

PART NUMBER[3]	OUTPUT CURRENT	PACKAGE[1]	BODY SIZE[2] (NOM)
TPSM82810	4A	SIL (µSiL, 14)	3.0mm × 4.0mm × 2.4mm
TPSM82813	3A	SIL (µSiL, 14)	3.0mm × 4.0mm × 2.4mm
		VCA (QFN, 13)	2.5mm × 3.0mm × 1.95mm
TPSM82812[4]	2A	VCA (QFN, 13)	2.5mm × 3.0mm × 1.95mm
TPSM82811[4]	1A		

(1) For more information, see Section 12.
(2) The package size (length × width × height) is a nominal value and includes pins, where applicable.
(3) See the *Device Comparison Table*.
(4) Preview information (not Production Data).

Schematic

TPSM82813PVCAR Efficiency; V_{IN} = 3.3V

Table of Contents

4 Device Comparison Table

DEVICE NUMBER	OUTPUT CURRENT	SPREAD SPECTRUM CLOCKING
TPSM8281**0**SILR	4A	OFF
TPSM8281**0S**SILR	4A	ON
TPSM8281**3**SILR	3A	OFF
TPSM8281**3S**SILR	3A	ON
TPSM8281**3P**VCAR	3A	OFF
TPSM8281**2P**VCAR[1]	2A	OFF
TPSM8281**1P**VCAR[1]	1A	OFF

(1)   Preview information (not production data).

5 Pin Configuration and Functions
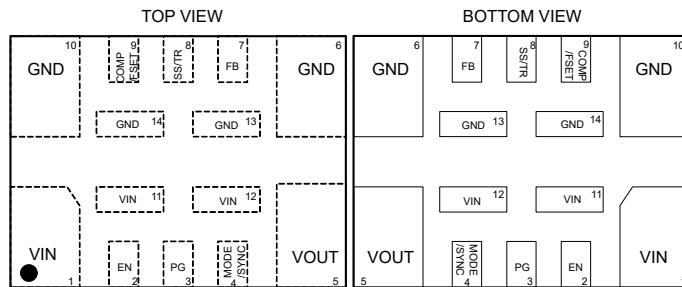

Figure 5-1. SIL Package, 14-Pin µSiL
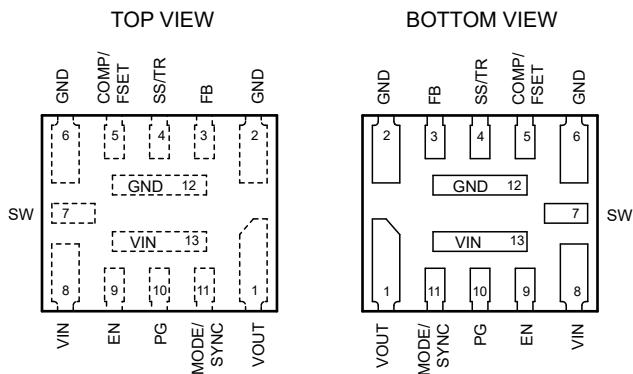
Figure 5-2. VCA Package, 13-Pin QFN

Table 5-1. Pin Functions

PIN			TYPE (1)	DESCRIPTION
NAME	SIL	VCA		
EN	2	9	I	This pin is the enable pin of the device. Connect to logic low to disable the device. Pull high to enable the device. Do not leave this pin unconnected.
FB	7	3	I	Voltage feedback input. Connect the output voltage resistor divider to this pin.
GND	6, 10, 13, 14	2, 6, 12		Ground pin
MODE /SYNC	4	11	I	The device runs in PFM/PWM mode when this pin is pulled low. When the pin is pulled high, the device runs in forced PWM mode. Do not leave this pin unconnected. The MODE/SYNC pin can also be used to synchronize the device to an external frequency. See *Section 9.3.2*.
COMP /FSET	9	5	I	Device compensation and frequency set input. A resistor from this pin to GND defines the compensation of the control loop as well as the switching frequency if not externally synchronized. The switching frequency is set to 2.25 MHz if the pin is tied to GND or VIN. See *Table 8-1*. Do not leave this pin unconnected.
PG	3	10	O	Open-drain power-good output with window comparator. This pin is pulled to GND while VOUT is outside the power-good threshold. This pin can be left open or tied to GND if not used. A pullup resistor can be connected to any voltage not larger than VIN.
SS/TR	8	4	I	Soft-start, tracking pin. A capacitor connected from this pin to GND defines the output voltage rise time. The pin can also be used as an input for tracking and sequencing - see *Voltage Tracking*.
VOUT	5	1		Output voltage pin. This pin is internally connected to the integrated inductor.
VIN	1, 11, 12	8, 13		Power supply input. Connect the input capacitor as close as possible between the VIN and GND pins.
SW	—	7	O	This pin is the switch pin of the converter. This pin is connected to the internal power MOSFET and the inductor. Leave this pin unconnected for best EMI performance.

(1)   I = input, O = output

6 Specifications

6.1 Absolute Maximum Ratings

Over operating junction temperature range (unless otherwise noted) [(1)]

		MIN	MAX	UNIT
Pin voltage[(2)]	VIN, EN, MODE/SYNC	–0.3	6.5	V
	SW (VCA package only)	–0.3	V_{IN}+0.3	V
	SW (transient for less than 10 ns, VCA package only, while switching)	–3	10	V
	FB	–0.3	4	V
	COMP/FSET, PG, SS/TR, VOUT	–0.3	V_{IN}+0.3	V
I_{SINK_PG}	Sink current at PG pin		10	mA
T_J	Operating junction temperature	–40	125	°C
T_{stg}	Storage temperature	–40	125	°C

(1)   Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2)   All voltage values are with respect to the network ground terminal.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 [(1)]	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 [(2)]	±500	

(1)   JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2)   JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{IN}	Supply voltage range	2.75		6	V
V_{OUT}	Output voltage range	0.6		5.5	V
C_{OUT}	Effective output capacitance[(1)]	27	47	470	µF
C_{IN}	Effective input capacitance[(1)]	5	10		µF
R_{CF}		4.5		100	kΩ
T_J	Operating junction temperature	-40		125	°C

(1)   The values given for all the capacitors in the table are effective capacitance, which includes the DC bias effect. Due to the DC bias effect of ceramic capacitors, the effective capacitance is lower than the nominal value when a voltage is applied. Please check the manufacturer´s DC bias curves for the effective capacitance vs DC voltage applied. Please see Section 9.3.3 about the output capacitance vs compensation setting and output voltage.

6.4 Thermal Information

THERMAL METRIC[(1)]		TPSM8281x				UNIT
		VCA (13 PINS)		µSIL (14 PINS)		
		EVM	JEDEC 51-7	EVM	JEDEC 51-5	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	27.4	73.0	35.0	52.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	n/a[(3)]	34.1	n/a[(3)]	52.0	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	n/a[(3)]	20.9	n/a[(3)]	16.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	(–3)[(2)]	(–1.4)[(2)]	11.1	12.8	°C/W
ψ_{JB}	Junction-to-board characterization parameter	10.2	20.6	14.8	16.9	°C/W

(1)   For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report and Thermal Consideration.
(2)   Case top temperature can be higher than temperature of active circuit because of inductor power dissipation. This results in a negative Junction-to-top characterization parameter.
(3)   Not applicable to an EVM

Product Folder Links: *TPSM82810 TPSM82813*

6.5 Electrical Characteristics

Over operating junction temperature (T_J = -40 °C to +125 °C) and V_{IN} = 2.75 V to 6 V. Typical values at V_{IN} = 5 V and T_J = 25 °C. (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
I_Q	Operating Quiescent Current	EN = high, I_{OUT} = 0mA, Device not switching		15	21	µA
I_{SD}	Shutdown Current	EN = 0V		0.11	18	µA
V_{UVLO}	Undervoltage Lockout Threshold	Rising Input Voltage	2.5	2.6	2.75	V
		Falling Input Voltage	2.25	2.5	2.6	V
T_{SD}	Thermal Shutdown Temperature	Rising Junction Temperature		170		°C
	Thermal Shutdown Hysteresis			15		
CONTROL (EN, SS/TR, PG, MODE/SYNC)						
V_{IH}	High Level Input Voltage for MODE/SYNC Pin		1.1			V
V_{IL}	Low Level Input Voltage for MODE/SYNC Pin				0.3	V
f_{SYNC}	Frequency Range on MODE/SYNC Pin for Synchronization		1.8		4	MHz
	Duty Cycle of Synchronization Signal at MODE/SYNC Pin		40%	50%	60%	
V_{IH}	Input Threshold Voltage for EN pin	Rising EN	1.06	1.1	1.15	V
V_{IL}	Input Threshold Voltage for EN pin	Falling EN	0.96	1.0	1.05	V
I_{LKG}	Input Leakage Current for EN, MODE/SYNC Pins	EN, MODE/SYNC = V_{IN} or GND			150	nA
V_{TH_PG}	UVP Power Good Threshold	Rising (%V_{FB})	92%	95%	98%	
	UVP Power Good Threshold	Falling (%V_{FB})	87%	90%	93%	
	OVP Power Good Threshold	Rising (%V_{FB})	107%	110%	113%	
	OVP Power Good Threshold	Falling (%V_{FB})	104%	107%	111%	
	Power Good De-glitch Time	for a high level to low level transition on power good		40		µs
V_{OL_PG}	Power Good Output Low Voltage	I_{PG} = 2mA		0.07	0.3	V
I_{LKG_PG}	Input Leakage Current for PG Pin	V_{PG} = 5V			100	nA
$I_{SS/TR}$	SS/TR Pin Source Current		2.1	2.5	2.8	µA
t_{delay}	Start-up Delay Time	Time from EN=high to start switching; V_{IN} applied already	135	200	450	µs
t_{ramp}	Ramp time; SS/TR Pin Open	Time from first switching pulse until 95% of nominal output voltage	100	150	200	µs
	Tracking Gain	$V_{FB}/V_{SS/TR}$		1		
	Tracking Offset	FB pin with $V_{SS/TR}$ = 0V		17		mV
POWER SWITCH						
$R_{DS(ON)}$	High-Side MOSFET ON-Resistance	$V_{IN} \geq$ 5V		37	60	mΩ
$R_{DS(ON)}$	Low-Side MOSFET ON-Resistance	$V_{IN} \geq$ 5V		15	35	mΩ
R_{DP}	Dropout resistance	100% mode. Maximum value at V_{IN} = 3.3V, T_J = 85°C		50	90	mΩ
I_{LIMH}	High-Side MOSFET Current Limit [1]	TPSM82810; V_{IN} = 3V to 6V	4.8	5.6	6.55	A
I_{LIMH}	High-Side MOSFET Current Limit[1]	TPSM82813; V_{IN} = 3V to 6V	3.9	4.5	5.25	A
I_{LIMNEG}	Negative Current Limit [1]	MODE/SYNC = HIGH		−1.8		A
f_S	PWM Switching Frequency Range		1.8	2.25	4	MHz
f_S	PWM Switching Frequency	with COMP/FSET tied to VIN or GND	2.025	2.25	2.475	MHz
	PWM Switching Frequency Tolerance	using a resistor from COMP/FSET to GND	−19%		18%	
$t_{on,min}$	Minimum on-time	V_{IN} = 3.3V		50	75	ns

Product Folder Links: *TPSM82810 TPSM82813*

6.5 Electrical Characteristics (continued)

Over operating junction temperature (T_J = -40 °C to +125 °C) and V_{IN} = 2.75 V to 6 V. Typical values at V_{IN} = 5 V and T_J = 25 °C. (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{off,min}$	Minimum off-time	V_{IN} = 3.3V		30		ns
OUTPUT						
V_{FB}	Feedback Voltage Accuracy	$V_{IN} \geq V_{OUT}$ + 1V; PWM mode	594	600	606	mV
		$V_{IN} \geq V_{OUT}$ + 1V; PFM mode $V_{OUT} \geq$ 1.5V; $C_{OUT,eff} \geq$ 27μF	594	600	612	mV
		1 V $\leq V_{OUT}$ < 1.5V; PFM mode $C_{OUT,eff} \geq$ 47μF	594	600	615	mV
I_{LKG_FB}	Input Leakage Current (FB pin)	V_{FB} = 0.6V		1	70	nA
V_{FB}	Feedback Voltage Accuracy with Voltage Tracking	$V_{IN} \geq V_{OUT}$ + 1V; PWM mode $V_{SS/TR}$ = 0.3V	297	300	321	mV
R_{dis}	Output Discharge Resistance			30	50	Ω

(1)   This is the static current limit. It can be temporarily higher in applications due to internal propagation delay (see Current Limit And Short Circuit Protection section).

6.6 Typical Characteristics

Figure 6-1. Quiescent Current

Figure 6-2. Shutdown Current

Figure 6-3. Oscillator Frequency vs Temperature (COMP/FSET tied to VIN or GND)

Figure 6-4. Dropout Resistance
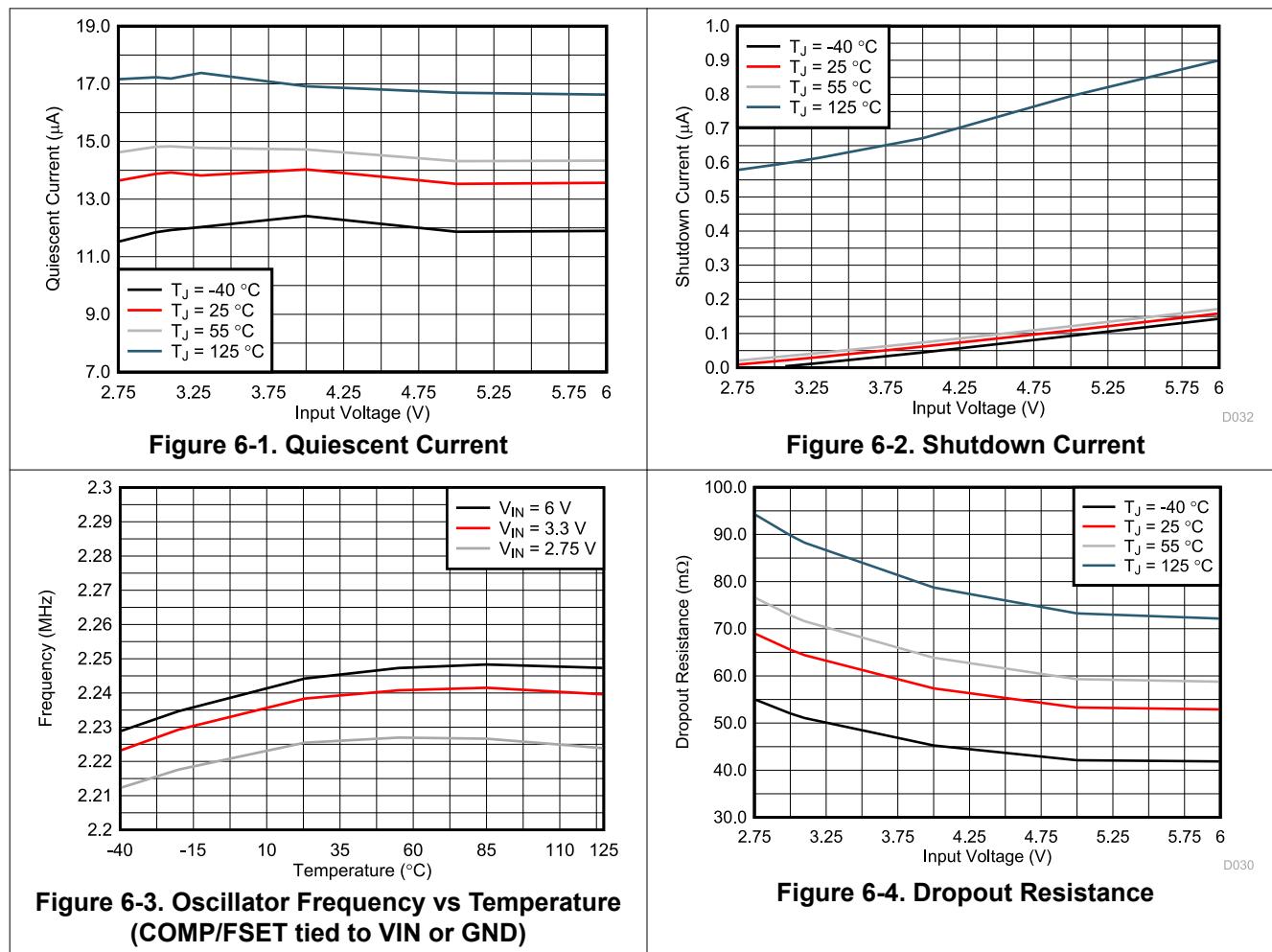
7 Parameter Measurement Information

7.1 Schematic
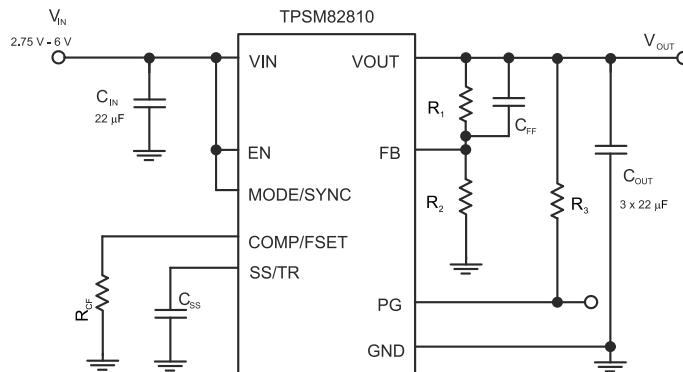
Figure 7-1. Measurement Setup for TPSM8281x

Table 7-1. List of Components for the TPSM8281xSILR

REFERENCE	DESCRIPTION	MANUFACTURER [1]
IC	TPSM82810 or TPSM82813	Texas Instruments
C_{IN}	22µF / X7T / 10V; GRM21BD71A226ME44	Murata
C_{OUT}	3 x 22µF / X7T / 10V; GRM21BD71A226ME44	Murata
C_{SS}	4.7nF	Any
R_{CF}	10kΩ	Any
C_{FF}	10pF	Any
R_1	Depending on VOUT	Any
R_2	Depending on VOUT	Any
R_3	100kΩ	Any

Table 7-2. List of Components for the TPSM8281xPVCAR

REFERENCE	DESCRIPTION	MANUFACTURER [1]
IC	TPSM82811PVCAR, TPSM82812PVCAR, TPSM82813PVCAR	Texas Instruments
C_{IN}	22µF / X7R / 10V; GRM21BZ1A226ME15L	Murata
C_{OUT}	2x 47uF / X6S / 6.3V; GRM21BC80J476ME01L	Murata
C_{SS}	4.7nF	Any
R_{CF}	10kΩ	Any
C_{FF}	10pF	Any
R_1	Depending on VOUT	Any
R_2	Depending on VOUT	Any
R_3	100kΩ	Any

(1)   See the *Third-party Products Disclaimer*.

Note

The input and output capacitor part numbers in each table above indicate the BOM used for parameter measurement. Both designs work in either configuration.

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8 Detailed Description

8.1 Overview

The TPSM8281x synchronous switch mode DC/DC converter power modules are based on a fixed-frequency peak current-mode control topology. The control loop is internally compensated. To optimize the bandwidth of the control loop to the wide range of output capacitance that can be used with the TPSM8281x, one of three internal compensation settings can be selected. See *Section 8.3.3*. The compensation setting is selected either by a resistor from COMP/FSET to GND, or by the logic state of this pin. The regulation network achieves fast and stable operation with small external components and low-ESR ceramic output capacitors.

The devices support fixed-frequency forced PWM operation with the MODE/SYNC pin tied to a logic high level. When the MODE/SYNC pin is set to a logic low level, the device operates in power save mode (PFM) at low-output currents and automatically transitions to fixed-frequency PWM mode at higher output currents. In PFM mode, the switching frequency decreases linearly based on the load to sustain high efficiency down to very low output currents. The device can be synchronized to an external clock signal in a range from 1.8MHz to 4MHz applied to the MODE/SYNC pin.

The TPSM8281xP versions in the VCA package use MagPack technology to deliver the highest-performance power module design. Leveraging Texas Instruments' proprietary integrated-magnetics packaging technology, MagPack (magnetics in package) power modules deliver industry-leading power density, high efficiency and good thermal performance, ease of use, and reduced EMI emissions.

8.2 Functional Block Diagram
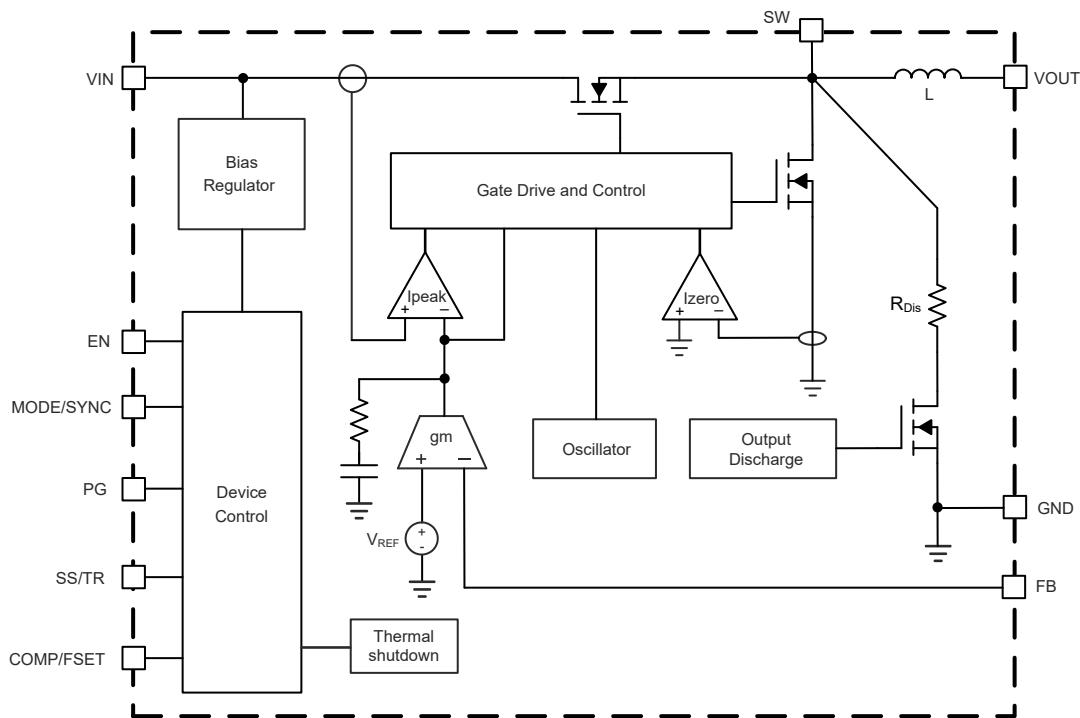
Note

SW is only accessable with the VCA package

8.3 Feature Description

8.3.1 Precise Enable (EN)

The TPSM8281x starts operation when the rising EN threshold is exceeded. For proper operation, the EN pin must be terminated and must not be left floating. Pulling the EN pin low forces the device into shutdown. In this mode, the internal high-side and low-side MOSFETs are turned off and the entire internal control circuitry is

switched off. The voltage applied at the EN pin of the TPSM8281x is compared to a fixed threshold of 1.1V for a rising voltage.

The enable input threshold for a falling edge is typically 100mV lower than the rising edge threshold. The Precise Enable input provides a user-programmable undervoltage lockout by adding a resistor divider to the input of the EN pin. The Precise Enable input also allows you to drive the pin by a slowly changing voltage and enables the use of an external RC network to achieve a precise power-up delay. See the *Achieving a Clean Start-up by Using a DC/DC Converter with a Precise Enable-pin Threshold* analog design journal for more details.

8.3.2 Output Discharge

The purpose of the discharge function is to make sure of a defined down-ramp of the output voltage when the device is disabled and keep the output voltage close to 0V when the device is off. The output discharge feature is only active after the TPSM8281x has been enabled at least once since the supply voltage was applied. The discharge function is enabled as soon as the device is disabled, in thermal shutdown, or in undervoltage lockout. The minimum supply voltage required for the discharge function to remain active is typically 1V.

8.3.3 COMP/FSET

This pin sets two different parameters independently:

- Internal compensation settings for the control loop (three settings available)
- The switching frequency in PWM mode from 1.8MHz to 4MHz

A resistor from COMP/FSET to GND changes the compensation as well as the switching frequency. The change in compensation adapts the device to different values of output capacitance. The resistor must be placed close to the pin to keep the parasitic capacitance on the pin to a minimum. The compensation setting is set after enabling the converter, so a change in the resistor during operation only has an effect on the switching frequency but not on the compensation.

To save external components, the pin can also be directly tied to VIN or GND to set a pre-defined switching frequency and compensation. Do not leave the pin floating.

The switching frequency must be selected based on the maximum input voltage and the output voltage to meet the specifications for the minimum on-time.

Example: V_{IN} = 5.5 V, V_{OUT} = 1 V

$$f_{Sw,max} = \frac{V_{OUT}}{V_{IN} \times t_{ON,min}} = \frac{1\,V}{5.5\,V \times 75\,ns} = 2.42\,MHz \tag{1}$$

The compensation range has to be chosen based on the minimum effective capacitance used. The capacitance can be increased from the minimum value as given in Table 8-1 up to the maximum of 470µF in all of the three compensation ranges. The higher compensation settings give better load transient response, when larger output capacitances are used. If the capacitance of an output changes during operation, for example, when load switches are used to connect or disconnect parts of the circuitry, the compensation has to be chosen for the minimum capacitance on the output. Compensating for large output capacitance but placing less capacitance on the output can lead to instability.

The switching frequency for the different compensation setting is determined by the following equations.

For compensation (comp) setting 1:

$$R_{CF}(k\Omega) = \frac{18MHz \times k\Omega}{f_S(MHz)} \tag{2}$$

For compensation (comp) setting 2:

$$R_{CF}(k\Omega) = \frac{60MHz \times k\Omega}{f_S(MHz)} \tag{3}$$

For compensation (comp) setting 3:

$$R_{CF}(k\Omega) = \frac{180MHz \times k\Omega}{f_S(MHz)} \qquad\qquad (4)$$

Table 8-1. Switching Frequency and Compensation

COMPENSATION	R_{CF}	SWITCHING FREQUENCY	MINIMUM OUTPUT CAPACITANCE FOR VOUT < 1V	MINIMUM OUTPUT CAPACITANCE FOR 1V ≤ VOUT < 3.3V	MINIMUM OUTPUT CAPACITANCE FOR VOUT ≥ 3.3V
for smallest output capacitance (comp setting 1)	10kΩ ... 4.5kΩ	1.8MHz (10kΩ) ... 4MHz (4.5kΩ) according to Equation 3	53μF	32μF	27μF
for medium output capacitance (comp setting 2)	33kΩ ... 15kΩ	1.8MHz (33kΩ) ... 4MHz (15kΩ) according to Equation 4	100μF	60μF	50μF
for large output capacitance (comp setting 3)	100kΩ ... 45kΩ	1.8MHz (100kΩ) ... 4MHz (45kΩ) according to Equation 5	200μF	120μF	100μF
for smallest output capacitance (comp setting 1)	tied to GND	internally fixed 2.25MHz	53μF	32μF	27μF
for large output capacitance (comp setting 3)	tied to V_{IN}	internally fixed 2.25MHz	200μF	120μF	100μF

Refer to Section 9.2.2.5 for further details on the output capacitance required depending on the output voltage. All values are the effective value of capacitance.

A too high resistor value for R_{CF} is read as "tied to V_{IN}", and a value below the lowest range as "tied to GND". The minimum output capacitance in Table 8-1 is for capacitors close to the output of the device. If the capacitance is distributed, a lower compensation setting can be required.

8.3.4 MODE/SYNC

When MODE/SYNC is set low, the device operates in PWM or PFM mode, depending on the output current. The MODE/SYNC pin forces PWM mode when set high. The pin also allows you to apply an external clock in a frequency range from 1.8MHz to 4MHz for external synchronization. When an external clock is applied, the device operates in PWM mode. As with the switching frequency selection, the specification for the minimum on-time has to be observed when applying the external clock signal. When using external synchronization, TI recommends to set the switching frequency as set by R_{CF} to a similar value as the externally applied clock. This ensures that the switching frequency stays in the same range when the external clock fails and the settling time to the internal clock is reduced. When there is no resistor from COMP/FSET to GND, but the pin is pulled high or low, external synchronization is not possible. An internal PLL allows you to change from an internal clock to external clock during operation. The synchronization to the external clock is done on the falling edge of the applied clock to the rising edge of the internal SW pin. The MODE/SYNC pin can be changed during operation. See Section 9.3.2 for more details.

8.3.5 Spread Spectrum Clocking (SSC) - TPSM8281xS

These devices offer spread spectrum clocking, where the switching frequency is randomly changed in PWM mode when the internal clock is used. The frequency variation is typically between the nominal switching frequency and up to 288kHz above the nominal switching frequency. When the device is externally synchronized, the TPSM8281xS follows the external clock and the internal spread spectrum block is turned off. SSC is also disabled during soft start.

8.3.6 Undervoltage Lockout (UVLO)

If the input voltage drops, the undervoltage lockout prevents mis-operation of the device by switching off both the MOSFETs. The device is fully operational for voltages above the rising UVLO threshold and turns off if the input voltage goes below the falling threshold.

8.3.7 Power-Good Output (PG)

The device has a power good output with window comparator. The PG pin goes high impedance after the FB pin voltage is above 95% and less than 107% of the nominal voltage, and is driven low after the voltage falls below typically 90% or higher than 110% of the nominal voltage. Table 8-2 shows the typical PG pin logic. The PG pin is an open-drain output and is specified to sink up to 2mA. The power good output requires a pullup resistor connected to any voltage rail less than VIN. The PG signal can be used for sequencing of multiple rails by connecting to the EN pin of other converters. If not used, the PG pin can be left floating or connected to GND.

Table 8-2. Power Good Pin Logic

DEVICE STATE		PG LOGIC STATUS	
		HIGH IMPEDANCE	LOW
Enabled (EN = High)	$0.57V \leq V_{FB} \leq 0.642V$	√	
	$V_{FB} < 0.54V$ or $V_{FB} > 0.66V$		√
Shutdown (EN = Low)			√
UVLO	$2V \leq V_{IN} < V_{UVLO}$		√
Thermal Shutdown	$T_J > T_{JSD}$		√
Power Supply Removal	$V_{IN} < 2V$	√	

The PG pin has a 40µs deglitch time on the falling edge.

8.3.8 Thermal Shutdown

The junction temperature (T_J) of the device is monitored by an internal temperature sensor. If T_J exceeds 170°C (typ), the device goes into thermal shutdown. Both the high-side and low-side power FETs are turned off and PG goes low. When T_J decreases below the hysteresis amount of typically 15°C, the converter resumes normal operation, beginning with soft start. During PFM, the thermal shutdown is not active.

8.4 Device Functional Modes

8.4.1 Pulse Width Modulation (PWM) Operation

The TPSM8281x has two operating modes: Forced PWM mode and PFM/PWM mode.

With the MODE/SYNC pin set to high, the TPSM8281x operates with pulse width modulation in continuous conduction mode (CCM). The switching frequency is either defined by a resistor from the COMP/FSET pin to GND or by an external clock signal applied to the MODE/SYNC pin.

8.4.2 Power Save Mode Operation (PFM/PWM)

When the MODE/SYNC pin is low, power save mode is allowed. The device operates in PWM mode as long as the peak inductor current is above the PFM threshold of about 1.2A. When the peak inductor current drops below the PFM threshold, the device starts to skip switching pulses.

In power save mode, the switching frequency decreases linearly with the load current to maintain high efficiency. The linear behavior of the switching frequency in power save mode is shown in Figure 8-1.
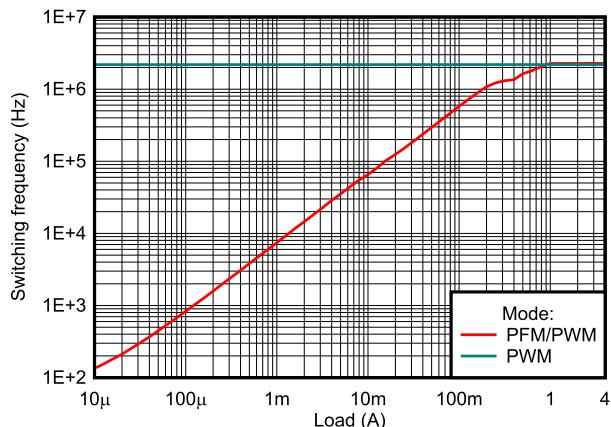
Figure 8-1. Switching Frequency versus Output Current (V_{IN} = 5V, V_{OUT} = 1.8V, R_{CF} = 8.06kΩ)

8.4.3 100% Duty-Cycle Operation

The device offers a low input-to-output voltage differential by entering 100% duty cycle mode. When the minimum off-time of typically 30ns is reached, the TPSM8281x skips switching cycles while approaching 100% mode. In 100% mode, the high-side MOSFET switch is constantly turned on. This is particularly useful in battery-powered applications to achieve longest operation time by taking full advantage of the whole battery voltage range. The minimum input voltage to maintain a minimum output voltage is given by:

$$V_{IN\,(min)} = V_{OUT\,(min)} + I_{OUT} \times R_{DP} \tag{5}$$

where

- R_{DP} is the resistance from V_{IN} to V_{OUT}, which includes the high-side MOSFET on-resistance and DC resistance of the inductor
- $V_{OUT\,(min)}$ is the minimum output voltage the load can accept

8.4.4 Current Limit and Short Circuit Protection

The TPSM8281x is protected against overload and short circuit events. If the inductor current exceeds the current limit I_{LIMH}, the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current. The high-side MOSFET turns on again only if the current in the low-side MOSFET has decreased below the low-side current limit. Due to internal propagation delays, the actual current can exceed the static current limit. The dynamic current limit is given as:

$$I_{peak(typ)} = I_{LIMH} + \frac{V_L}{L} \cdot t_{PD} \tag{6}$$

where

- I_{LIMH} is the static current limit, as specified in the electrical characteristics
- L is the effective inductance (typically 470nH)
- V_L is the voltage across the inductor (V_{IN} - V_{OUT})
- t_{PD} is the internal propagation delay of typically 50ns

The dynamic peak current is calculated as follows:

$$I_{peak(typ)} = I_{LIMH} + \frac{V_{IN} - V_{OUT}}{L} \cdot 50ns \tag{7}$$

The low-side MOSFET also contains a negative current limit to prevent excessive current from flowing back through the inductor to the input. If the low-side sinking current limit is exceeded, the low-side MOSFET is turned

off. In this scenario, both MOSFETs are off until the start of the next cycle. The negative current limit is only active in Forced PWM mode.

8.4.5 Soft Start / Tracking (SS/TR)

The internal soft-start circuitry controls the output voltage slope during start-up. This control avoids excessive inrush current and makes sure of a controlled output voltage rise time. This control also prevents unwanted voltage drops from high impedance power sources or batteries. When EN is set high, the device starts switching after a delay of about 200µs. Then V_{OUT} rises with a slope controlled by an external capacitor connected to the SS/TR pin.

A capacitor connected from SS/TR to GND is charged with 2.5µA by an internal current source during soft start until the capacitor reaches the reference voltage of 0.6V. After reaching 0.6V, the SS/TR pin voltage is clamped internally while the SS/TR pin voltage keeps rising to a maximum of about 3.3V. The capacitance required to set a certain ramp-time (t_{ramp}) is:

$$C_{SS}\left[nF\right] = \frac{2.5\mu A \cdot t_{ramp}\left[ms\right]}{0.6V}$$

(8)

Leaving the SS/TR pin un-connected provides the fastest start-up ramp of 150µs typically. If the device is set to shutdown (EN = GND), undervoltage lockout, or thermal shutdown, an internal resistor pulls the SS/TR pin to GND tomake sure of a proper low level. Returning from those states causes a new start-up sequence.

A voltage applied at the SS/TR pin can also be used to track a controller voltage. The output voltage follows this voltage in both directions up and down in forced PWM mode. In PFM mode, the output voltage decreases based on the load current. An external voltage applied on SS/TR is internally clamped to the feedback voltage (0.6V). TI recommends to set the final value of the external voltage on SS/TR to be slightly above 0.6V to make sure the device operates with the internal reference voltage when the power-up sequencing is finished. See *Section 9.3.1*.

Product Folder Links: *TPSM82810 TPSM82813*

9 Application and Implementation

> **Note**
>
> Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The TPSM8281x are synchronous step-down converter power modules. The required power inductor is integrated inside the TPSM8281x. The inductor is shielded and has an inductance of 470 nH with approximately a ±20% tolerance.

The VCA MagPack package includes a 470nH shielded inductor and shields the entire IC for better EMI performance. The smaller size and lower height provide higher power density compared to the SIL package.

The 1A, 2A, and 3A VCA versions have the same efficiency and performance, differing only in the output current rating. The versions are pin-to-pin compatible with higher-current versions: TPSM82814PVCAR (4A) and TPSM82816PVCAR (6A).

The 3A SIL version has the same efficiency and performance as the 4A SIL version. Both versions differ only in the output current rating. The versions are pin-to-pin compatible with the higher-current TPSM82816SIER (6A) version.

9.2 Typical Application
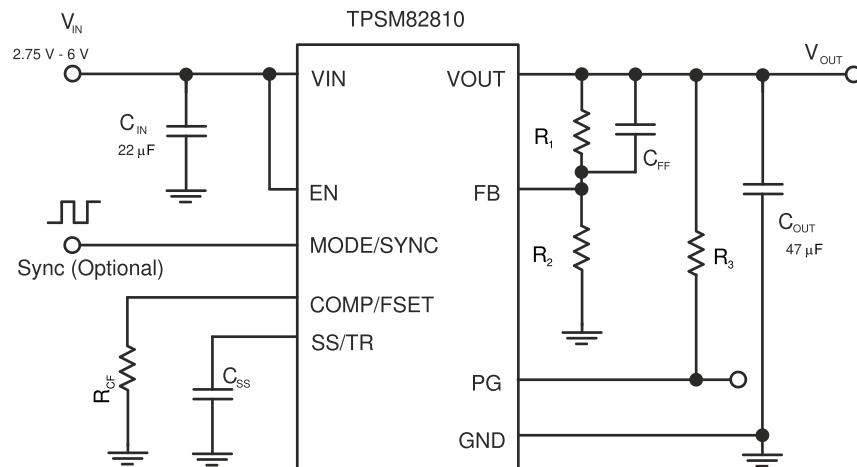
Figure 9-1. Typical Application Schematic

9.2.1 Design Requirements

The design guidelines provide a component selection to operate the device within the recommended operating conditions.

9.2.2 Detailed Design Procedure

9.2.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPSM8281x device with the WEBENCH® Power Designer.

1. In the part number field start entering the part number if you have a preference and wait until a part list will appear and populate. If there is no preference leave this field blank.
2. In the next section (auto-filled if you started with a part number) enter the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.

3. In the "Design Considerations" section select your design priorities.
4. View your design proposal and compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:
*   Run electrical simulations to see important waveforms and circuit performance
*   Export customized schematic and layout into popular CAD formats
*   Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools here: Design and simulation tools.

9.2.2.2 Setting the Output Voltage

The output voltage of the TPSM8281x is adjustable. Choose resistors R1 and R2 to set the output voltage within a range of 0.6V to 5.5V according to Equation 10. To keep the feedback (FB) net robust from noise, set R2 equal to or lower than 100kΩ to have at least 6µA of current in the voltage divider.

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1 \right) = R2 \times \left(\frac{V_{OUT}}{0.6V} - 1 \right)$$

(9)

Lower values of FB resistors achieve better noise immunity at the expense of reduced light load efficiency. Details about optimizing feedback resistor networks can be found in the analog design journal article Design considerations for a resistive feedback divider in a DC/DC converter.

9.2.2.3 Feedforward capacitor

A feedforward capacitor (C_{FF}) is recommended in parallel with R_1 in order to improve the transient response. Regardless of the FB resistor values, the C_{FF} value must always be 10pF.

9.2.2.4 Input Capacitor

For most applications, a 22µF nominal ceramic capacitor is recommended. The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. A X7R or X7T multilayer ceramic capacitor (MLCC) is recommended for best filtering and must be placed between VIN and GND as close as possible to those pins. For applications with ambient temperatures below 85°C, a capacitor with X5R dielectric can be used. Ceramic capacitors have a DC-Bias effect, which has a strong influence on the final effective capacitance. Choose the right capacitor carefully in combination with considering the package size and voltage rating. The minimum required input capacitance is 5µF.

9.2.2.5 Output Capacitor

The architecture of the TPSM8281x allows the use of ceramic output capacitors which have low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep the low resistance up to high frequencies and to get a narrow capacitance variation with temperature, TI recommends to use an X7R or X7T dielectric. At temperatures below 85°C, an X5R dielectric can be used.

Using a higher capacitance value has advantages like smaller voltage ripple and a tighter DC output accuracy in power save mode. By changing the device compensation with a resistor from COMP/FSET to GND, the device can be compensated in three steps based on the minimum capacitance used on the output. The maximum capacitance is 470µF in any of the compensation settings. The minimum capacitance required on the output depends on the compensation setting and output voltage as shown in Table 8-1. For output voltages below 1V, the minimum required capacitance increases linearly from 32µF at 1V to 53µF at 0.6V with the compensation setting for smallest output capacitance. Other compensation settings scale the same. Ceramic capacitors have a DC-Bias effect, which has a strong influence on the final effective capacitance. Choose the right capacitor carefully in combination with considering the package size and voltage rating.

9.2.3 Application Curves

T_A = 25°C, V_{IN} = 5V, V_{OUT} = 1.8V, 1.8MHz, PWM mode, BOM = Table 7-1 unless otherwise noted.

V_{IN} = 3.3V   PFM, SIL Package T_A = 25°C
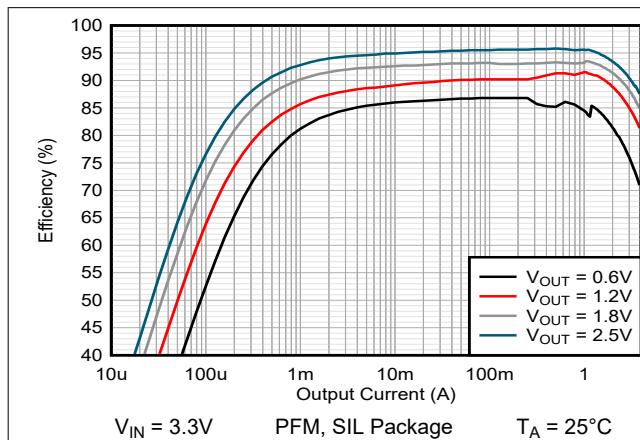
Figure 9-2. Efficiency vs Output Current

V_{IN} = 3.3V   PWM, SIL Package T_A = 25°C
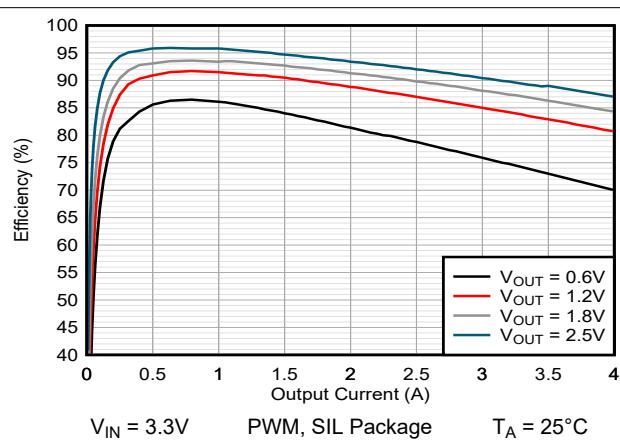
Figure 9-3. Efficiency vs Output Current

V_{IN} = 3.3V   PFM, SIL Package T_A = 85°C
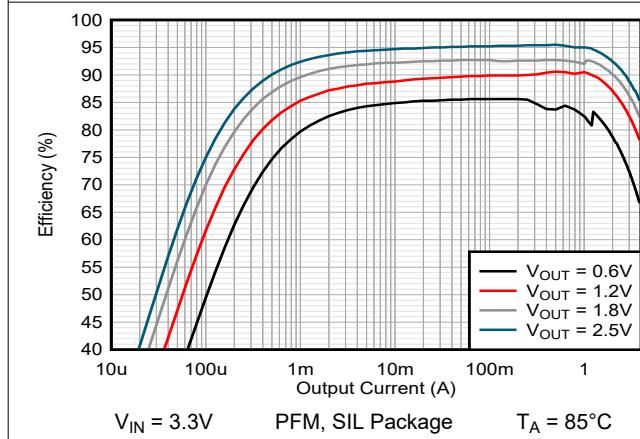
Figure 9-4. Efficiency vs Output Current

V_{IN} = 3.3V   PWM, SIL Package T_A = 85°C
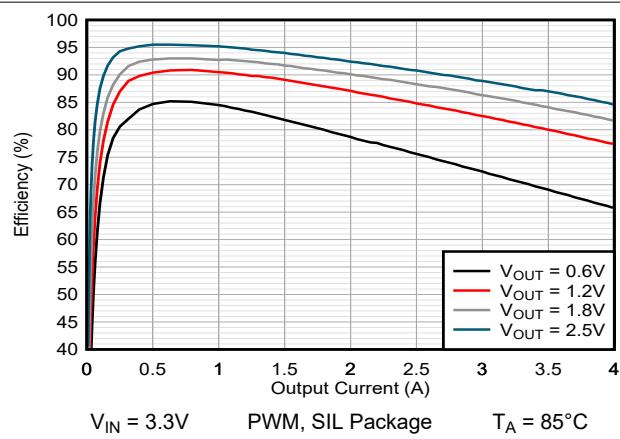
Figure 9-5. Efficiency vs Output Current

V_{IN} = 5V   PFM, SIL Package T_A = 25°C
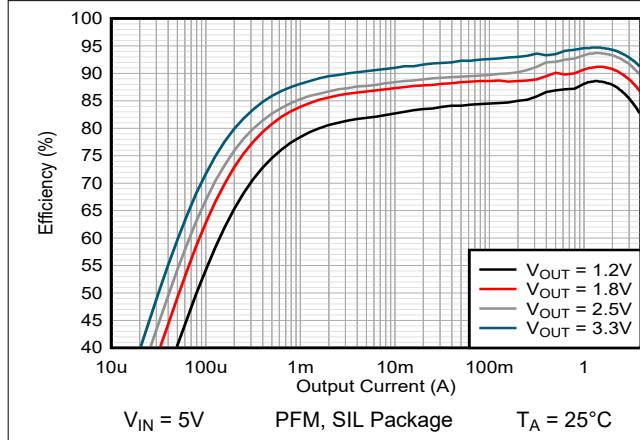
Figure 9-6. Efficiency vs Output Current

V_{IN} = 5V   PWM, SIL Package T_A = 25°C
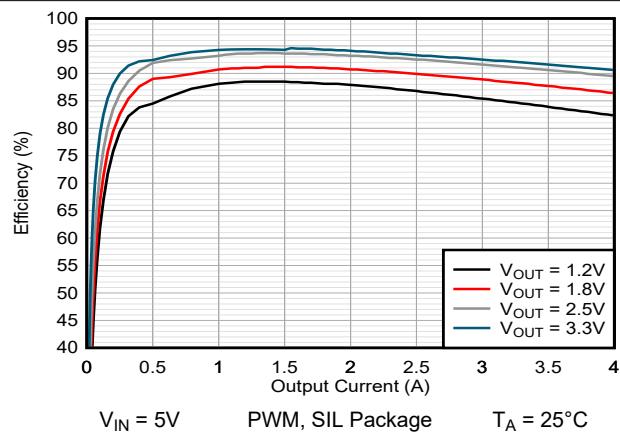
Figure 9-7. Efficiency vs Output Current

Figure 9-8. Efficiency vs Output Current

V_{IN} = 5V   PFM, SIL Package T_A = 85°C

Figure 9-9. Efficiency vs Output Current

V_{IN} = 5V   PWM, SIL Package T_A = 85°C

Figure 9-10. Efficiency vs Output Current

V_{IN} = 3.3V   PFM, VCA Package T_A = 25°C

Figure 9-11. Efficiency vs Output Current

V_{IN} = 3.3V   PWM, VCA Package T_A = 25°C

Figure 9-12. Efficiency vs Output Current

V_{IN} = 3.3V   PFM, VCA Package T_A = 85°C

Figure 9-13. Efficiency vs Output Current

V_{IN} = 3.3V   PWM, VCA Package T_A = 85°C

Product Folder Links: *TPSM82810 TPSM82813*

Figure 9-14. Efficiency vs Output Current

V_{IN} = 5V   PFM, VCA Package   T_A = 25°C
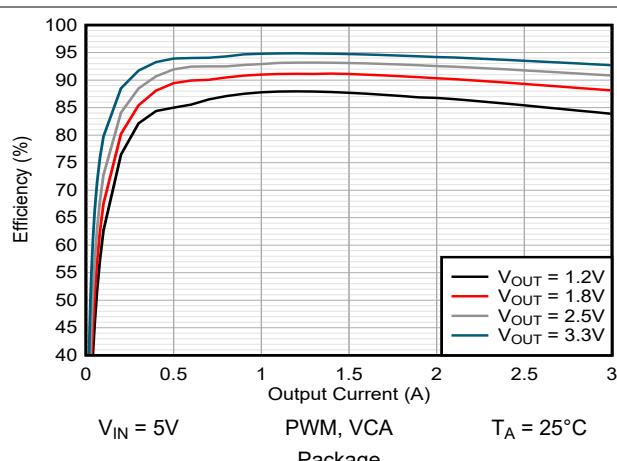
Figure 9-15. Efficiency vs Output Current

V_{IN} = 5V   PWM, VCA Package   T_A = 25°C
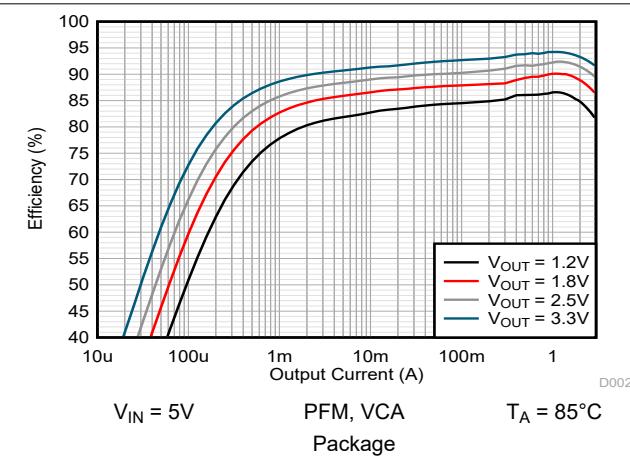
Figure 9-16. Efficiency vs Output Current

V_{IN} = 5V   PFM, VCA Package   T_A = 85°C
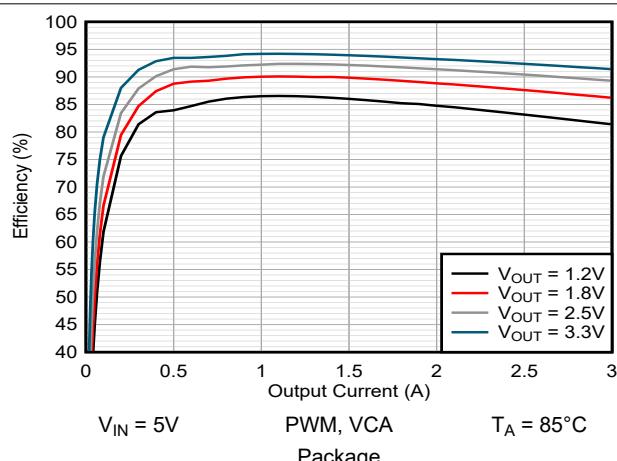
Figure 9-17. Efficiency vs Output Current

V_{IN} = 5V   PWM, VCA Package   T_A = 85°C
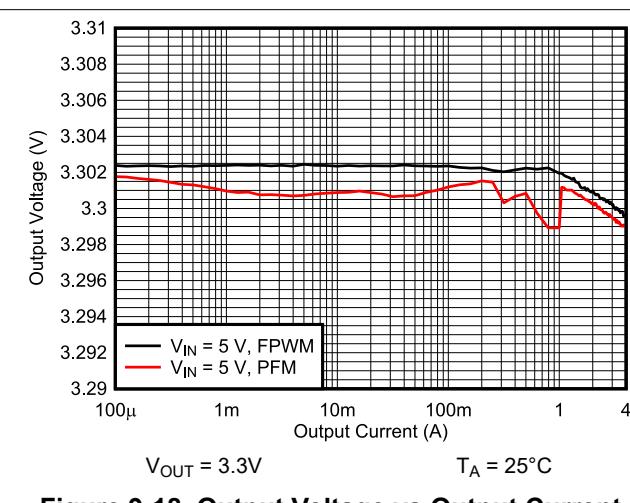
Figure 9-18. Output Voltage vs Output Current

V_{OUT} = 3.3V   T_A = 25°C
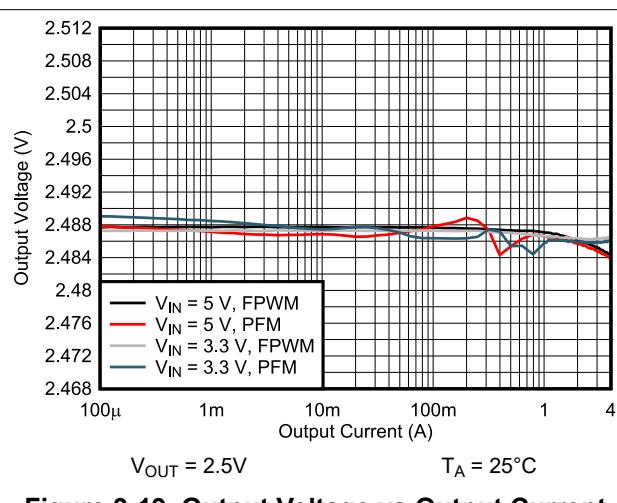
Figure 9-19. Output Voltage vs Output Current

V_{OUT} = 2.5V   T_A = 25°C
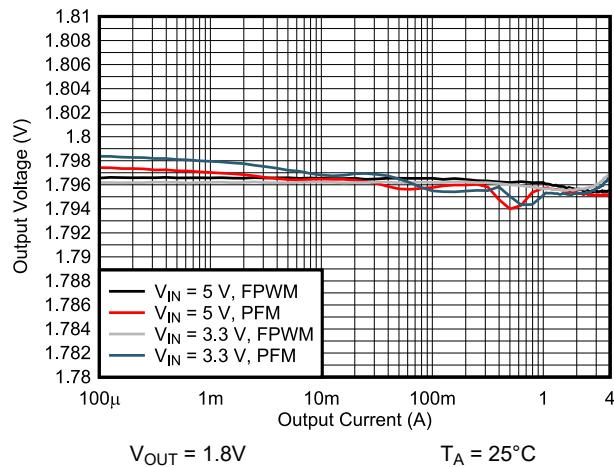
Figure 9-20. Output Voltage vs Output Current

V_{OUT} = 1.8V T_A = 25°C
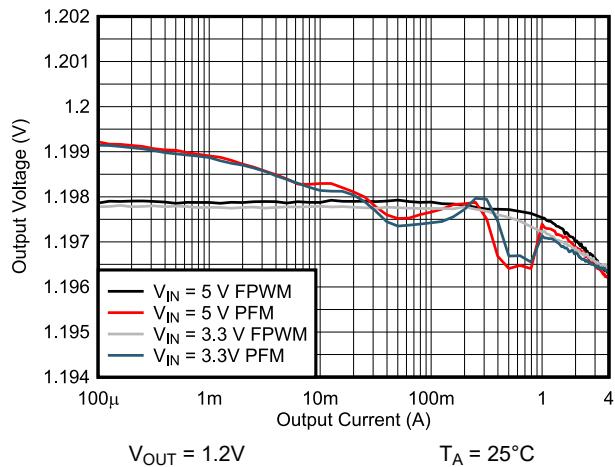
Figure 9-21. Output Voltage vs Output Current

V_{OUT} = 1.2V T_A = 25°C
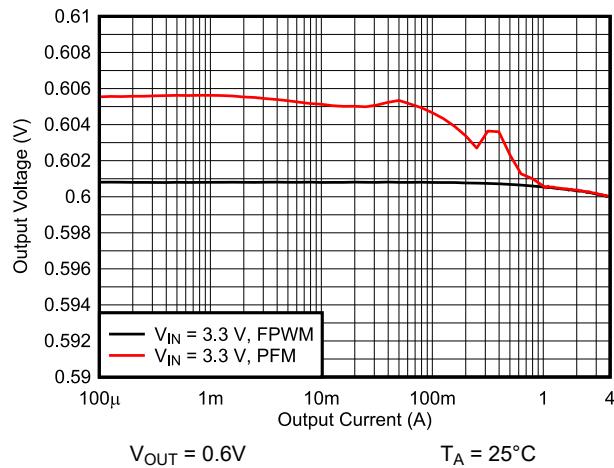
Figure 9-22. Output Voltage vs Output Current

V_{OUT} = 0.6V T_A = 25°C

$R_{θJA}$ = 35.0°C/W   SIL Package $T_{J,max}$ = 125°C
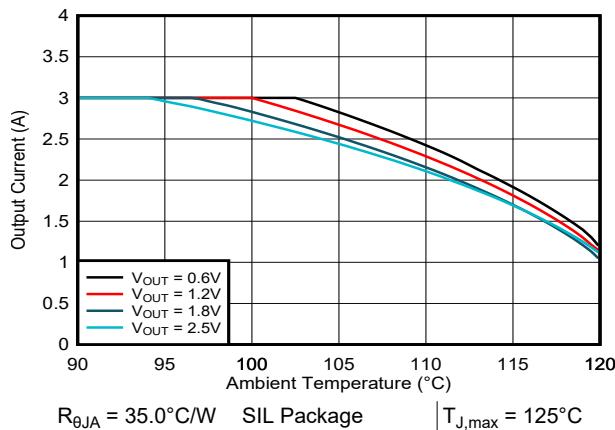
Figure 9-23. Safe Operating Area V_{IN} = 3.3V

$R_{θJA}$ = 35.0°C/W   SIL Package $T_{J,max}$ = 125°C
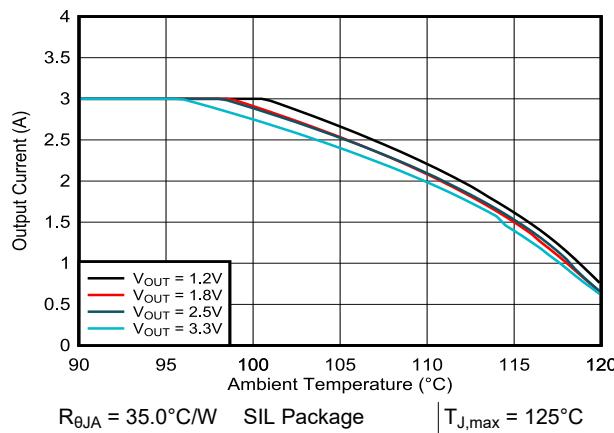
Figure 9-24. Safe Operating Area V_{IN} = 5.0V

$R_{θJA}$ = 27.4°C/W   VCA Package $T_{J,max}$ = 125°C
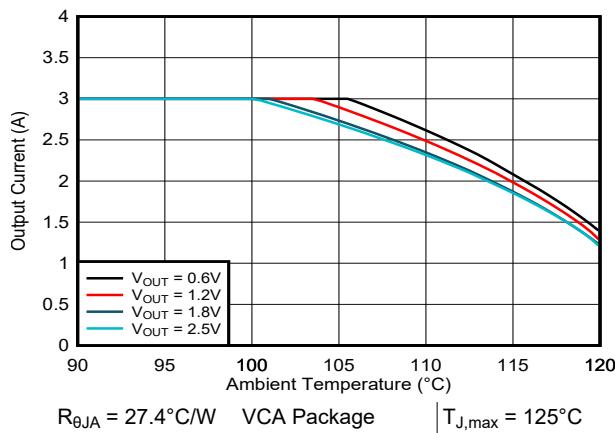
Figure 9-25. Safe Operating Area V_{IN} = 3.3V

Product Folder Links: *TPSM82810 TPSM82813*

$R_{\theta JA}$ = 27.4°C/W   VCA Package | $T_{J,max}$ = 125°C
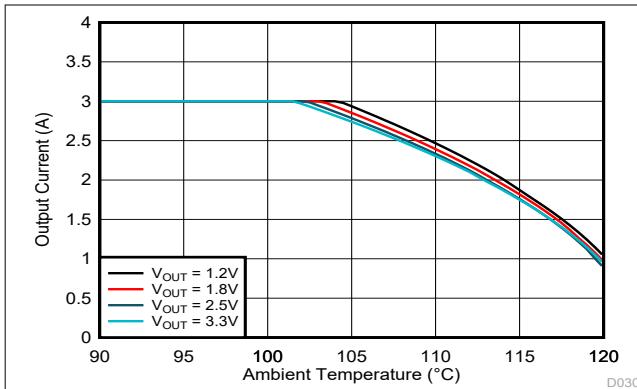
Figure 9-26. Safe Operating Area V_{IN} = 5.0V

| V_{OUT} = 1.8V | PWM | T_A = 25°C |
| V_{IN} = 5.0V | | I_{OUT} = 0A to 4A to 0A |
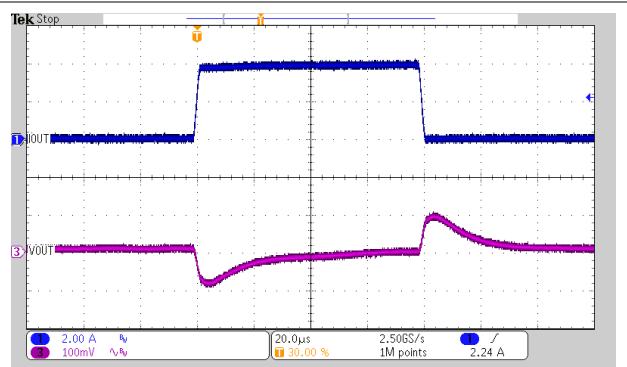
Figure 9-27. Load Transient Response

| V_{OUT} = 1.8V | PFM | T_A = 25°C |
| V_{IN} = 5.0V | | I_{OUT} = 0A to 4A to 0A |
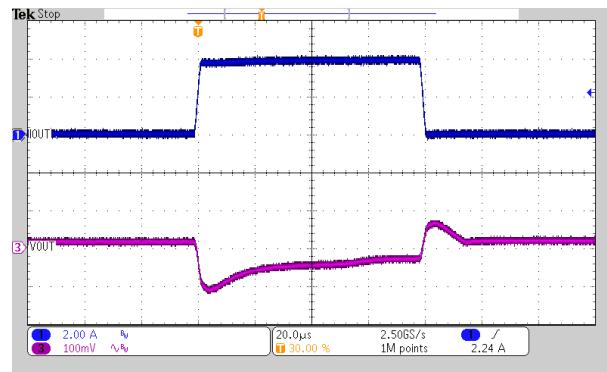
Figure 9-28. Load Transient Response

| V_{OUT} = 1.8V | PWM | T_A = 25 °C |
| I_{OUT} = 4A | V_{IN} = 5.0V | BW = 20MHz |
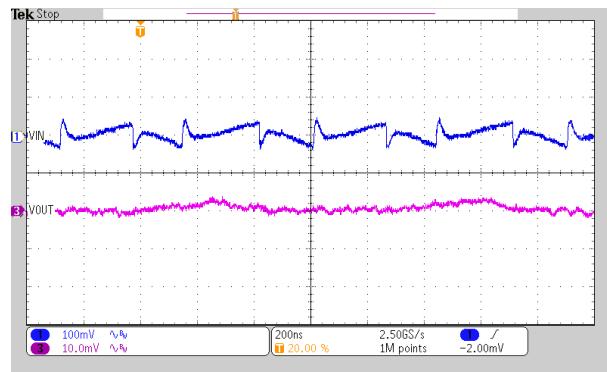
Figure 9-29. Output and Input Voltage Ripple

| V_{OUT} = 1.8V | PFM | T_A = 25°C |
| I_{OUT} = 0A | V_{IN} = 5.0V | BW = 20MHz |
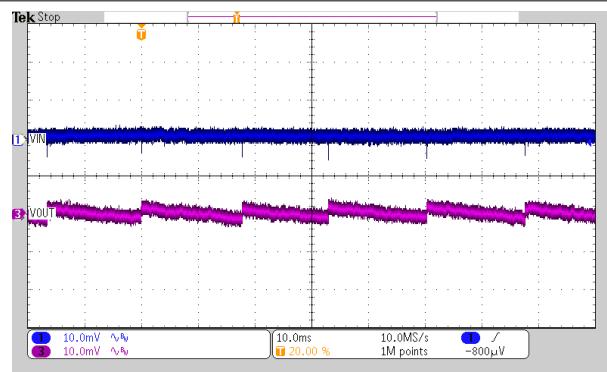
Figure 9-30. Output and Input Voltage Ripple

| V_{OUT} = 1.8V | PWM | T_A = 25°C |
| I_{OUT} = 4A | V_{IN} = 5V | C_{SS} = 4.7nF |
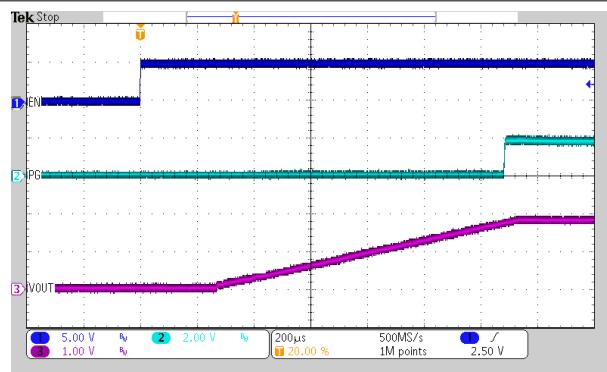
Figure 9-31. Start-Up Timing

Product Folder Links: TPSM82810 TPSM82813

| V_{OUT} = 1.8V | PFM | T_A = 25°C |
| I_{OUT} = 0A | V_{IN} = 5V | C_{SS} = 4.7nF |

Figure 9-32. Start-Up Timing
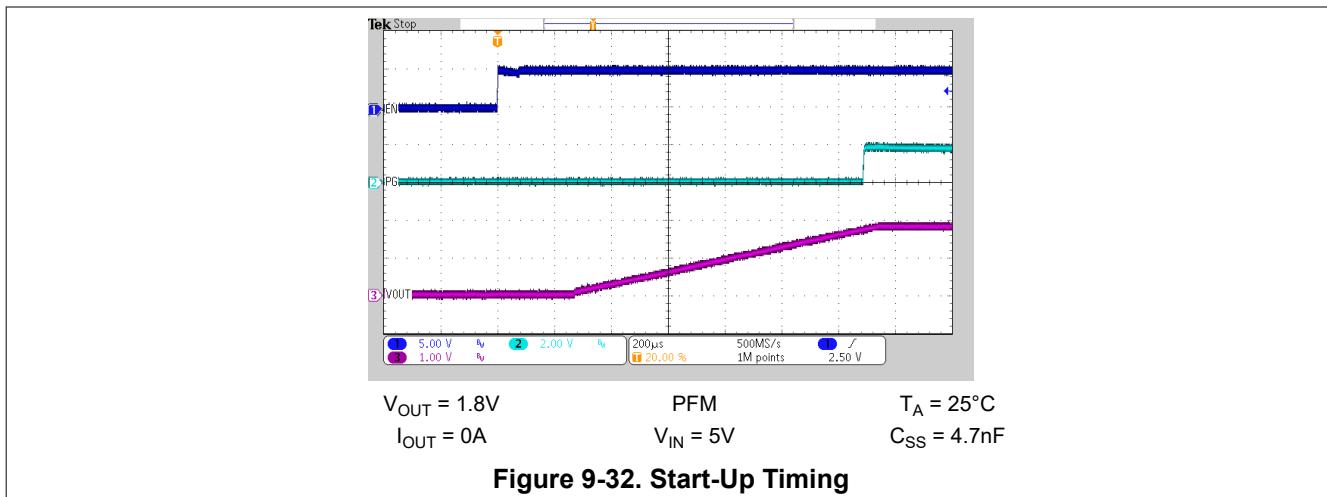
9.3 System Examples

9.3.1 Voltage Tracking

The SS/TR pin is externally driven by another voltage source to achieve output voltage tracking. The application circuit is shown in Figure 9-33. From 0V to 0.6V, the internal reference voltage to the internal error amplifier follows the SS/TR pin voltage. When the SS/TR pin voltage is above 0.6V, the voltage tracking is disabled and the FB pin voltage is regulated at 0.6V. The device achieves ratiometric or coincidental (simultaneous) output tracking, as shown in Figure 9-34.

The R2 value must be set properly to achieve accurate voltage tracking by taking the 2.5µA charging current into account. 1kΩ or smaller is a sufficient value for R2. For decreasing SS/TR pin voltage, the device does not sink current from the output when the device is in PFM mode. The resulting decrease of the output voltage can be slower than the SS/TR pin voltage if the load is light.

When driving the SS/TR pin with an external voltage, do not exceed the voltage rating of the SS/TR pin which is VIN+0.3V.
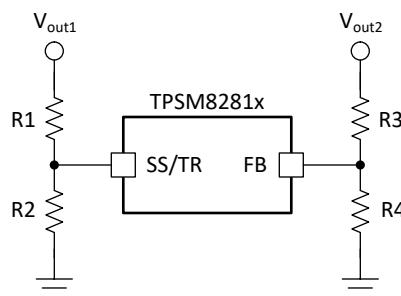
Figure 9-33. Schematic for Output Voltage Tracking
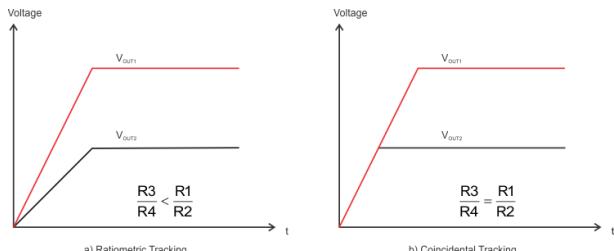
Figure 9-34. Output Voltage Tracking

Product Folder Links: *TPSM82810 TPSM82813*

9.3.2 Synchronizing to an External Clock

The TPSM8281x can be synchronized by applying a clock on the MODE/SYNC pin. There is no need for any additional circuitry. See Figure 9-35. The clock can be applied, changed, and removed during operation. The value of the R_{CF} resistor is recommended to be chosen such that the internally defined frequency and the externally-applied frequency are close to each other to have a fast settling time to the external clock. Synchronizing to a clock is not possible, if the COMP/FSET pin is connected to Vin or GND. Figure 9-36 and Figure 9-37 show the external clock being applied and removed. When an external clock is applied, the device operates in PWM mode.
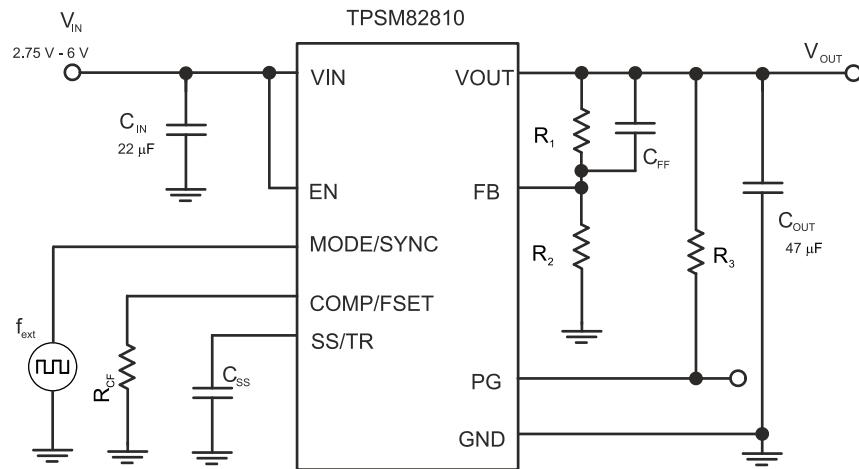
Figure 9-35. Frequency Synchronization

V_{IN} = 5V R_{CF} = 8.06kΩ I_{OUT} = 0.1A
V_{OUT} = 1.8V f_{EXT} = 2.5MHz
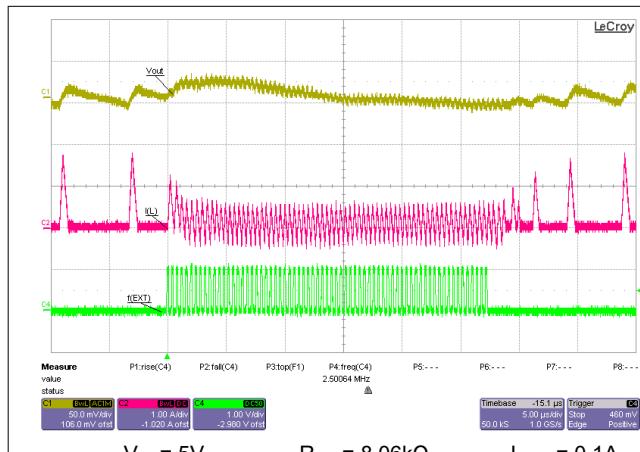
Figure 9-36. Applying and Removing the Synchronization Signal (PFM)

V_{IN} = 5V R_{CF} = 8.06kΩ I_{OUT} = 1A
V_{OUT} = 1.8V f_{EXT} = 2.5MHz
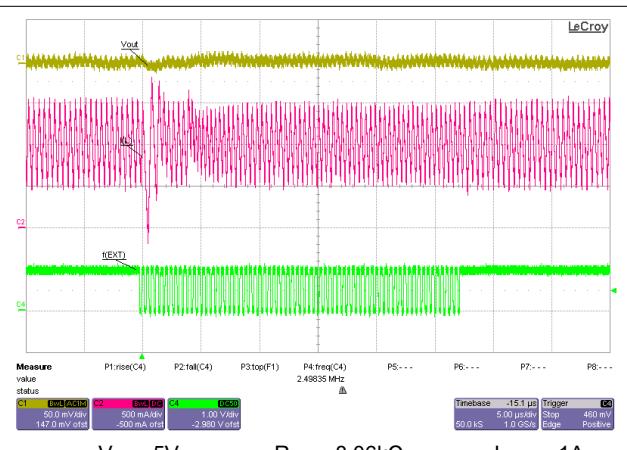
Figure 9-37. Applying and Removing the Synchronization Signal (FPWM)

9.4 Power Supply Recommendations

The TPSM8281x device family has no special requirements for the input power supply. The output current of the input power supply needs to be rated according to the supply voltage, output voltage, and output current of the TPSM8281x.

Product Folder Links: *TPSM82810 TPSM82813*

9.5 Layout

9.5.1 Layout Guidelines

A proper layout is critical for the operation of any switched mode power supply, especially at high switching frequencies. Therefore, the PCB layout of the TPSM8281x demands careful attention to make sure of best performance. A poor layout can lead to issues like bad line and load regulation, instability, increased EMI radiation, and noise sensitivity. Refer to the *Five Steps to a Great PCB Layout for a Step-Down Converter* analog design journal for a detailed discussion of general best practices. Specific recommendations for the device are listed below.

- The input capacitor must be placed as close as possible to the VIN and GND pins of the device. This is the most critical component placement. Route the input capacitor directly to the VIN and GND pins avoiding vias.
- Place the output capacitor ground close to the VOUT and GND pins and route directly avoiding vias.
- Place the FB resistors, R1 and R2, and the feedforward capacitor C_{FF} close to the FB pin and place C_{SS} close to the SS/TR pin to minimize noise pickup.
- Place the R_{CF} resistor close to the COMP/FSET pin to minimize the parasitic capacitance.
- The recommended layout is implemented on the EVM and shown in the *EVM User's Guide* and in *Section 9.5.2*.
- The recommended land pattern for the TPSM8281x is shown at the end of this data sheet. For best manufacturing results, create the pads as solder mask defined (SMD), when some pins (such as VIN, VOUT, and GND) are connected to large copper planes. Using SMD pads keeps each pad the same size and avoids solder pulling the device during reflow.

9.5.2 Layout Examples

The example below shows a cut-out from the layout of the MagPack evaluation module. To further reduce EMI, current loops are kept small and noisy traces kept short.
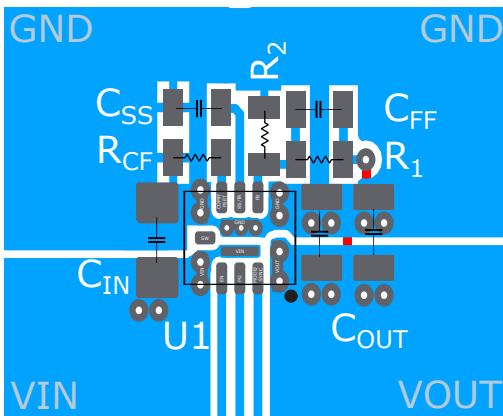

Figure 9-38. Example Layout VCA Package

The same rules also apply to the layout with the SIL package. The pin-outs of both the SIL and the VCA package are optimized for short connections between the device and input or output capacitors. The copper keepout (only for the SIL package) is for top copper layer only. Other PCBs layers can enter this keepout.
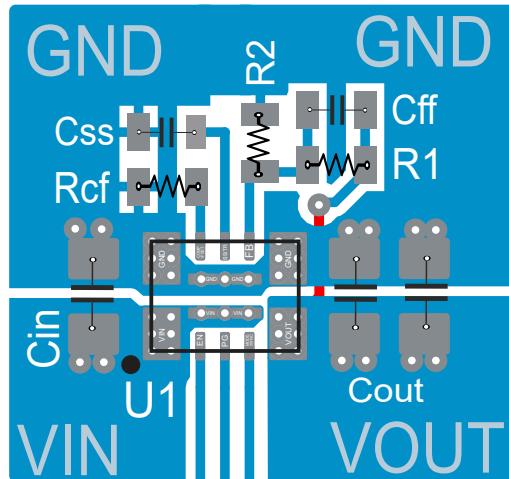
Figure 9-39. Example Layout SIL Package

9.5.2.1 Thermal Consideration

The TPSM8281x module temperature must be kept less than the maximum rating of 125°C. The following are three basic approaches for enhancing thermal performance:

- Improve the power dissipation capability of the PCB design.
- Improve the thermal coupling of the component to the PCB.
- Introduce airflow into the system.

To estimate the approximate module temperature of the TPSM8281x, apply the typical efficiency stated in this data sheet to the desired application condition to compute the power dissipation of the module. Then, calculate the module temperature rise by multiplying the power dissipation by the thermal resistance. For more details on how to use the thermal parameters in real applications, see the application notes: *Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs* and *Semiconductor and IC Package Thermal Metrics*.

The thermal values in *Thermal Information* used the recommended land pattern, shown at the end of this data sheet, including the 18 vias as shown. The TPSM8281x was simulated on a PCB defined by JEDEC 51-7. The 9 vias on the GND pins were connected to copper on other PCB layers, while the remaining 9 vias were not connected to other layers.

10 Device and Documentation Support

10.1 Device Support

10.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

10.1.2 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPSM8281x device with the WEBENCH® Power Designer.

1. In the part number field start entering the part number if you have a preference and wait until a part list will appear and populate. If there is no preference leave this field blank.
2. In the next section (auto-filled if you started with a part number) enter the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
3. In the "Design Considerations" section select your design priorities.
4. View your design proposal and compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:
*   Run electrical simulations to see important waveforms and circuit performance
*   Export customized schematic and layout into popular CAD formats
*   Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools here: Design and simulation tools.

10.2 Documentation Support

10.2.1 Related Documentation

For related documentation see the following:

*   Texas Instruments, *TPSM82810EVM-089 Evaluation Module* user's guide
*   Texas Instruments, *Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs* application note
*   Texas Instruments, *Five Steps to a Great PCB Layout for a Step-Down Converter* analog design journal
*   Texas Instruments, *Design Considerations for a Resistive Feedback Divider in a DC/DC Converter* analog design journal
*   Texas Instruments, *Achieving a Clean Start-up by Using a DC/DC Converter with a Precise Enable-pin Threshold* analog design journal

10.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.5 Trademarks

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All trademarks are the property of their respective owners.

10.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.7 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

VCA0013A

PACKAGE OUTLINE

QFN-FCMOD - 2 mm max height
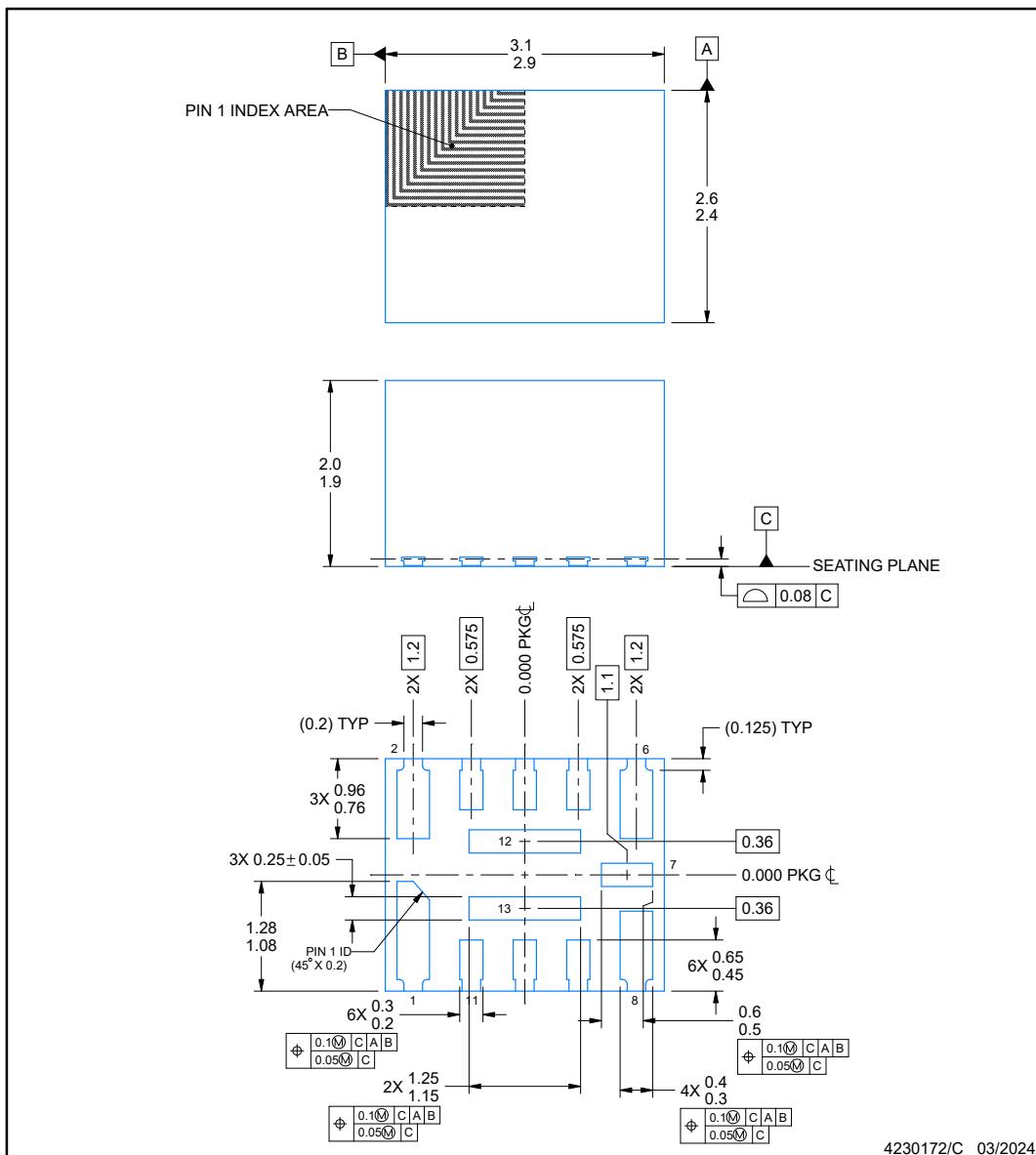
PLASTIC QUAD FLATPACK - NO LEAD

4230172/C   03/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

Texas Instruments
www.ti.com

EXAMPLE BOARD LAYOUT

VCA0013A

QFN-FCMOD - 2 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X

SOLDER MASK DETAILS

NON SOLDER MASK DEFINED

SOLDER MASK DEFINED
PINS 1, 2, 6, 8, 12 & 13

4230172/C   03/2024
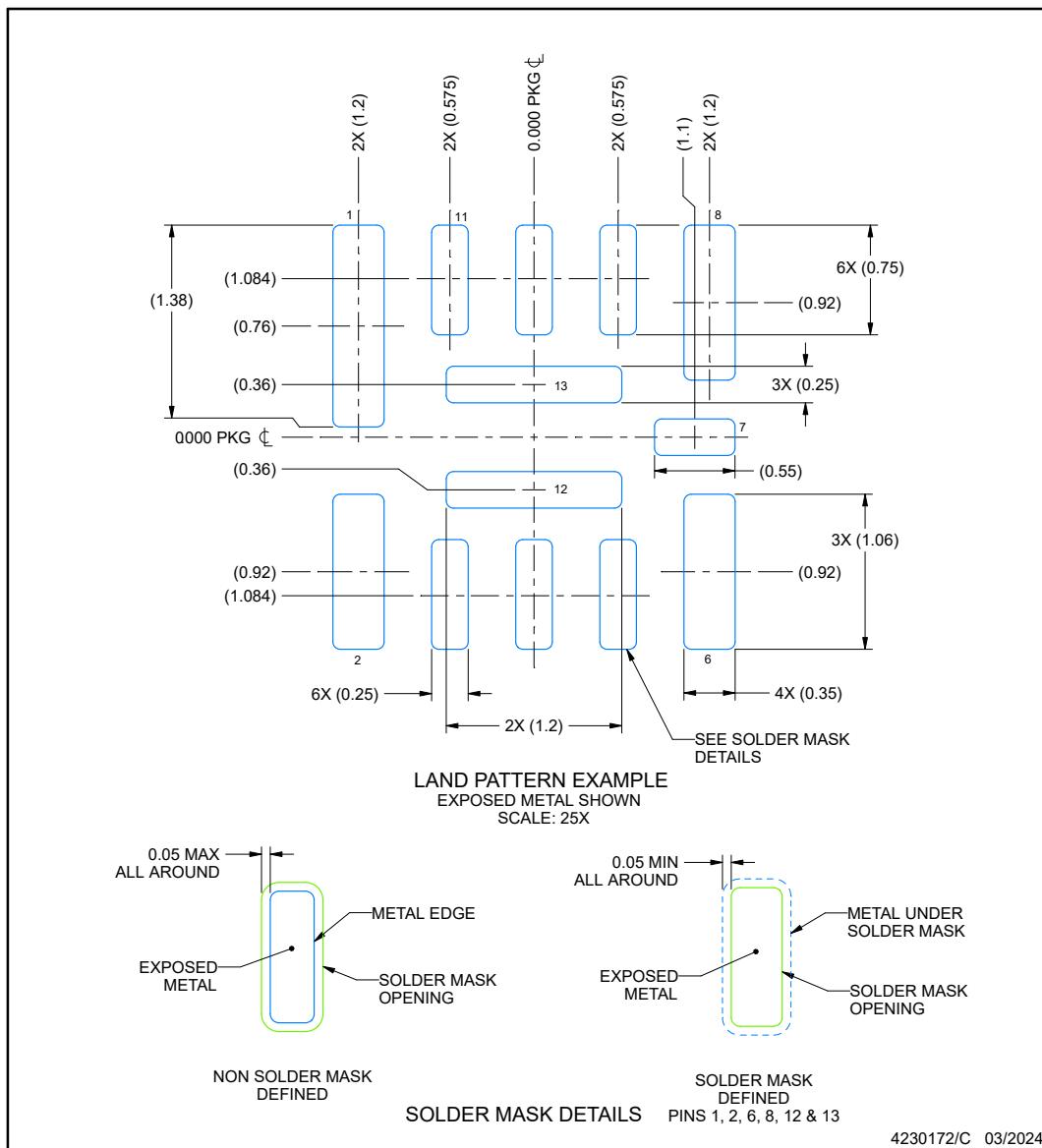
NOTES: (continued)

3. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271)

TEXAS INSTRUMENTS
www.ti.com

Product Folder Links: *TPSM82810 TPSM82813*

EXAMPLE STENCIL DESIGN

VCA0013A

QFN-FCMOD - 2 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE: 25X

4230172/C   03/2024
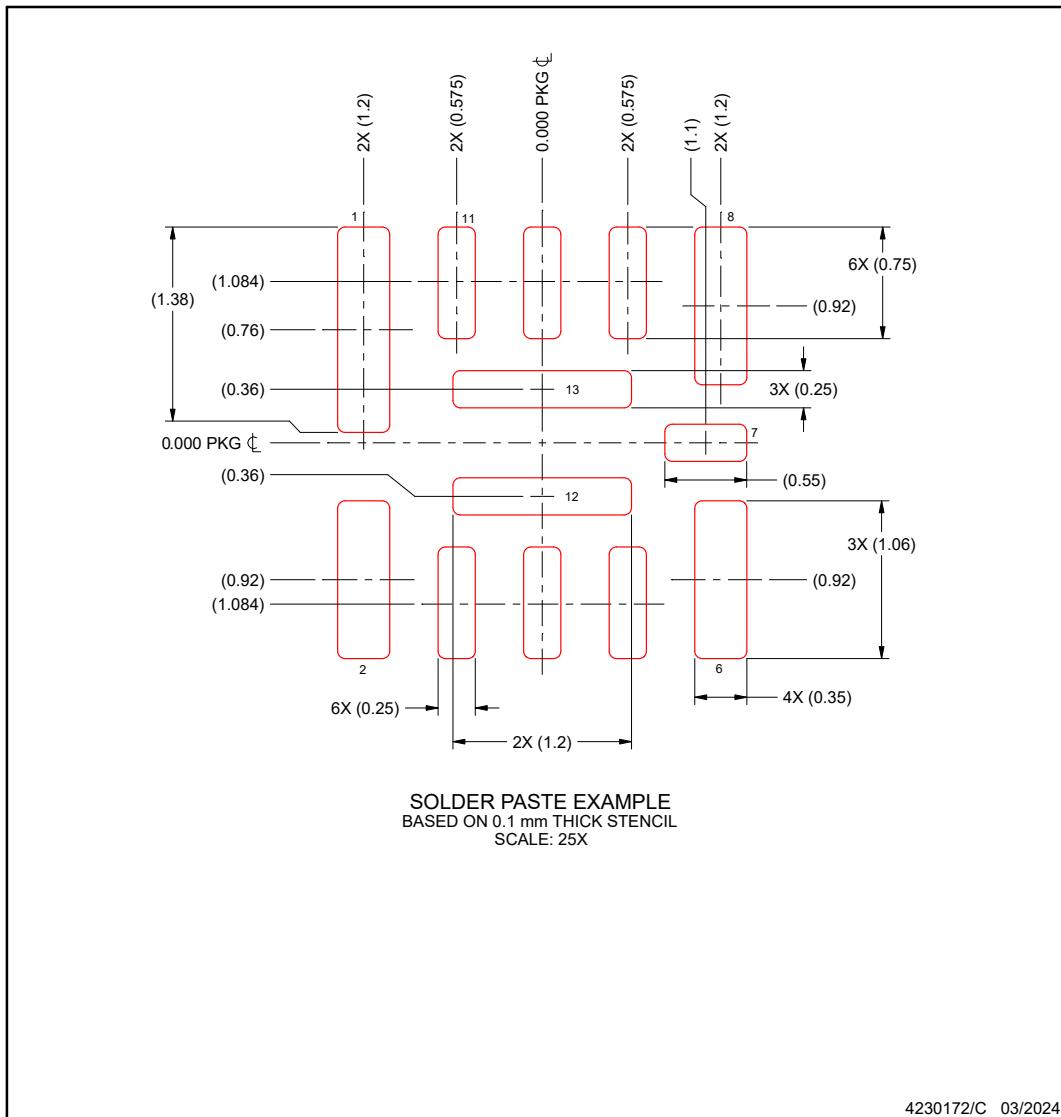
NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

Texas
INSTRUMENTS
www.ti.com

Product Folder Links: *TPSM82810 TPSM82813*

PACKAGE OUTLINE

SIL0014B-C01

uSIP™ - 2.4 mm max height

MICRO SYSTEM IN PACKAGE

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Pick and place nozzle ⌀ 1.3 mm or smaller recommended.
4. The package thermal pads must be soldered to the printed circuit board for thermal and mechanical performance.

4229075/A   09/2022
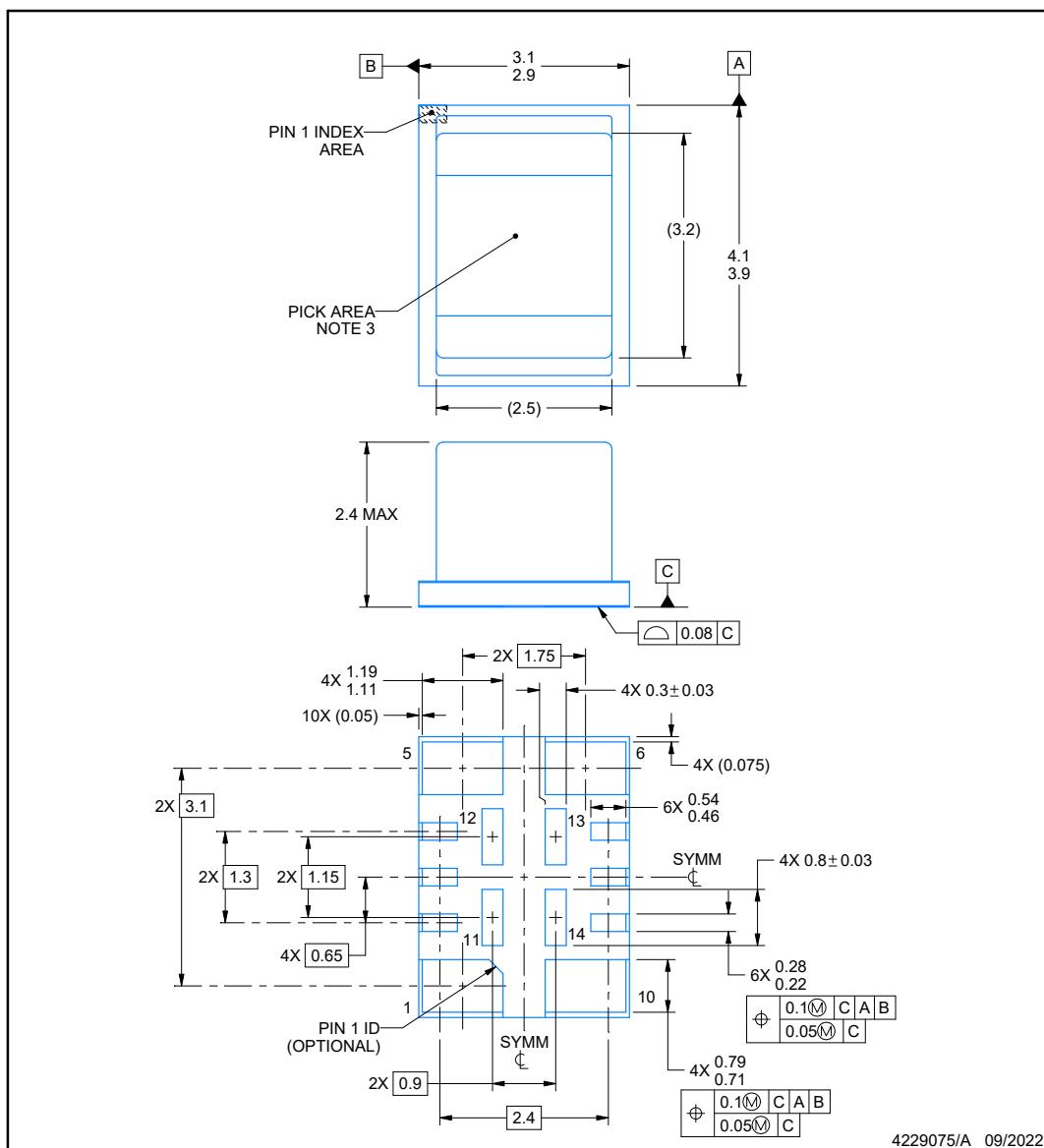
MicroSiP is a trademark of Texas Instruments

Texas Instruments
www.ti.com

Product Folder Links: *TPSM82810 TPSM82813*

EXAMPLE BOARD LAYOUT

SIL0014B-C01 uSIP™ - 2.4 mm max height

MICRO SYSTEM IN PACKAGE

LAND PATTERN EXAMPLE
SCALE:15X

SOLDER MASK OPENING
METAL
NON SOLDER MASK DEFINED

0.05 MAX ALL AROUND

0.05 MIN ALL AROUND

SOLDER MASK OPENING
METAL UNDER SOLDER MASK
SOLDER MASK DEFINED
PADS 1, 5, 6, 10 AND 11 - 14

SOLDER MASK DETAILS
NOT TO SCALE

4229075/A 09/2022
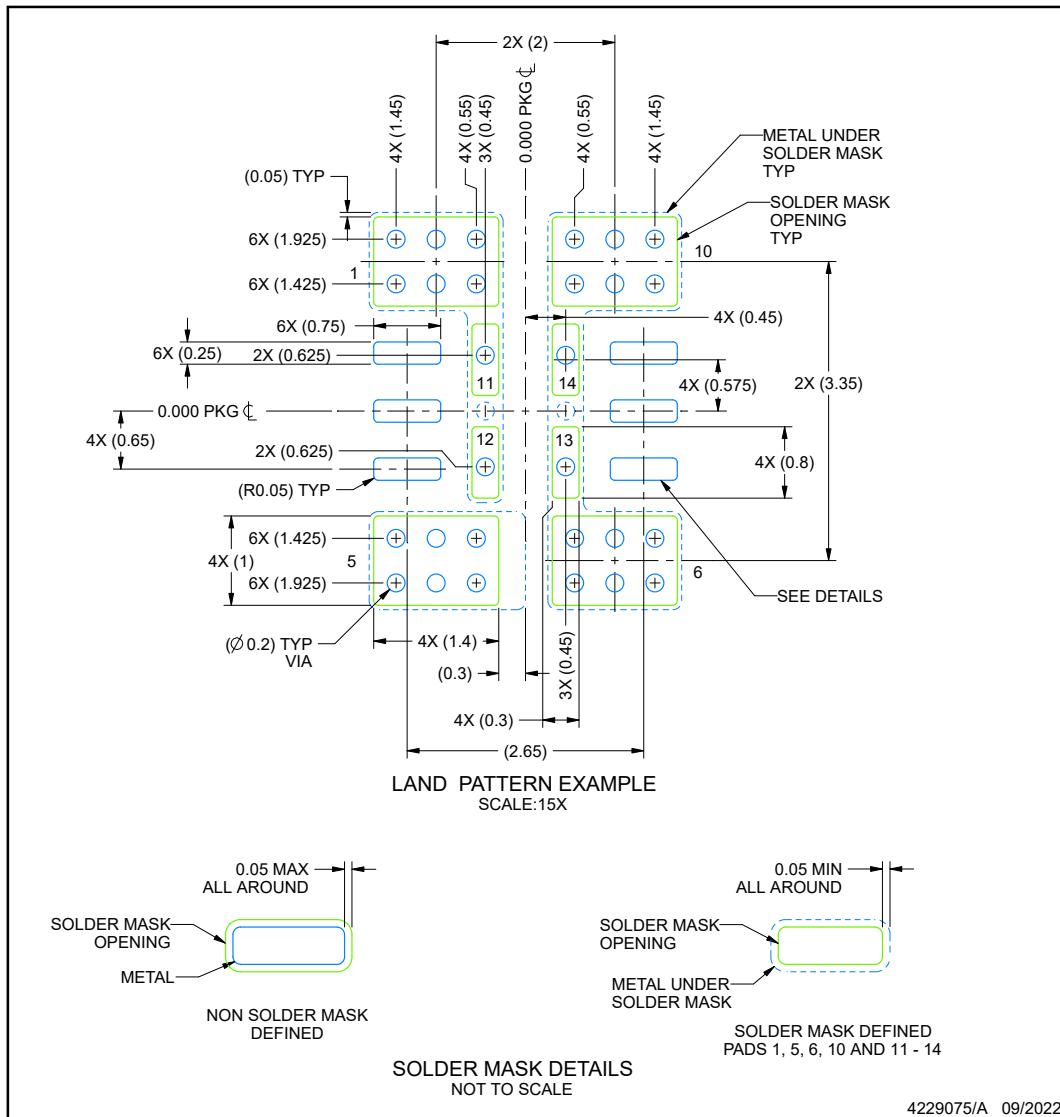
NOTES: (continued)

5. This package is designed to be soldered to thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
6. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

SIL0014B-C01

uSIP ™ - 2.4 mm max height

MICRO SYSTEM IN PACKAGE

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:25X
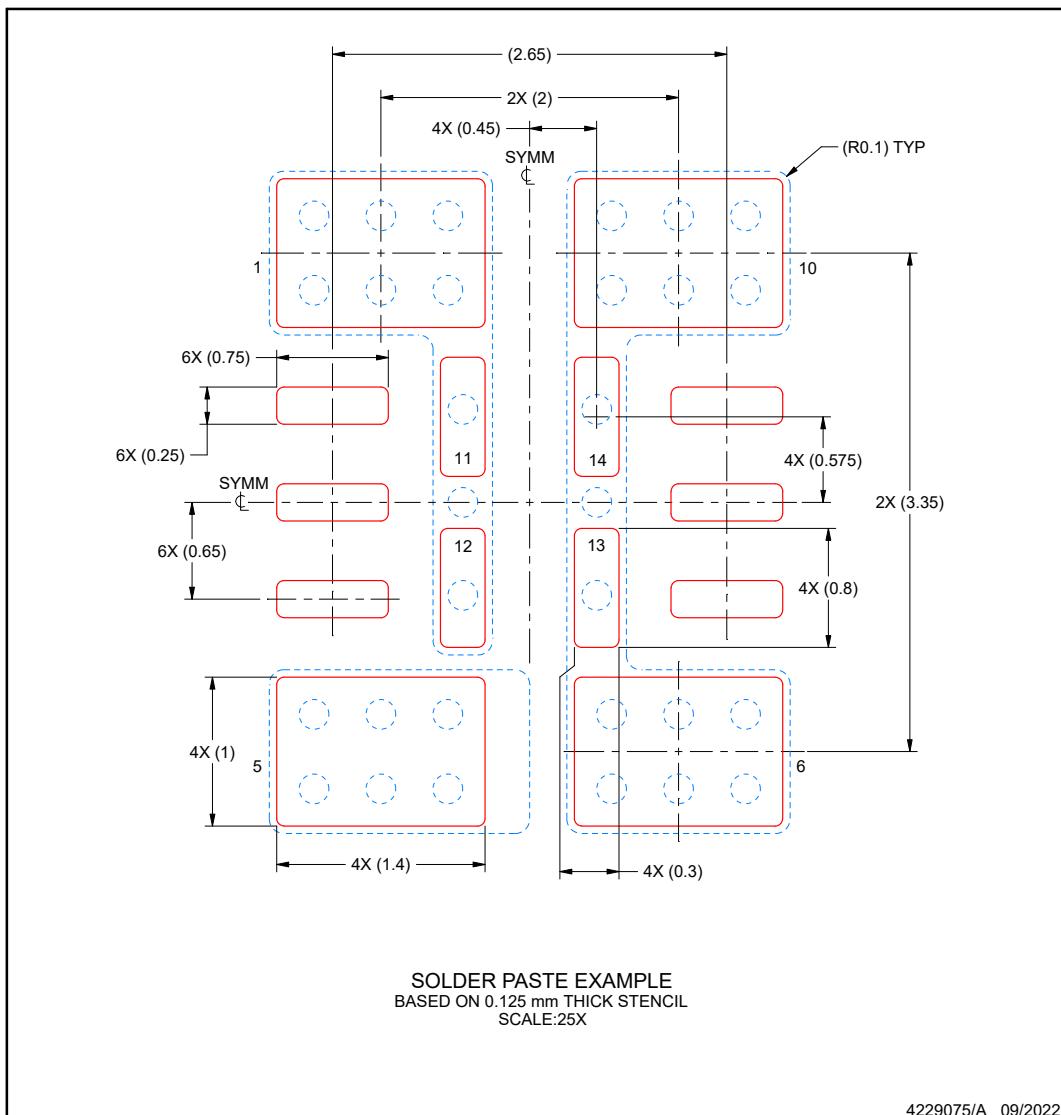
4229075/A   09/2022

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

TEXAS INSTRUMENTS
www.ti.com

Product Folder Links: *TPSM82810 TPSM82813*

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPSM82810SILR	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	FG
TPSM82810SILR.A	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	FG
TPSM82810SSILR	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	GC
TPSM82810SSILR.A	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	GC
TPSM82813PVCAR	Active	Production	QFN-FCMOD (VCA) | 13	2500 | LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	3HAI
TPSM82813PVCAR.A	Active	Production	QFN-FCMOD (VCA) | 13	2500 | LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	3HAI
TPSM82813SILR	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	GD
TPSM82813SILR.A	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	GD
TPSM82813SSILR	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	HF
TPSM82813SSILR.A	Active	Production	uSiP (SIL) | 14	3000 | LARGE T&R	Yes	NIAU	Level-2-260C-1 YEAR	-40 to 125	HF

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS
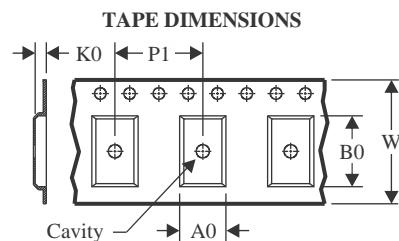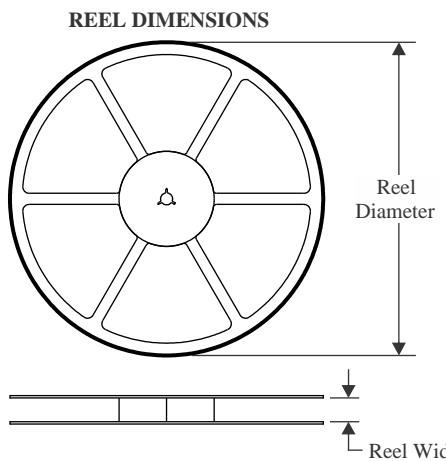
TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
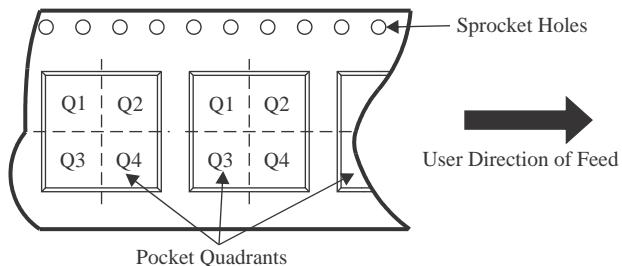
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPSM82810SILR	uSiP	SIL	14	3000	178.0	13.2	3.3	4.3	2.6	8.0	12.0	Q1
TPSM82810SSILR	uSiP	SIL	14	3000	178.0	13.2	3.3	4.3	2.6	8.0	12.0	Q1
TPSM82813PVCAR	QFN-FCMOD	VCA	13	2500	330.0	12.4	3.3	2.8	2.2	8.0	12.0	Q1
TPSM82813SILR	uSiP	SIL	14	3000	178.0	13.2	3.3	4.3	2.6	8.0	12.0	Q1
TPSM82813SSILR	uSiP	SIL	14	3000	178.0	13.2	3.3	4.3	2.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS
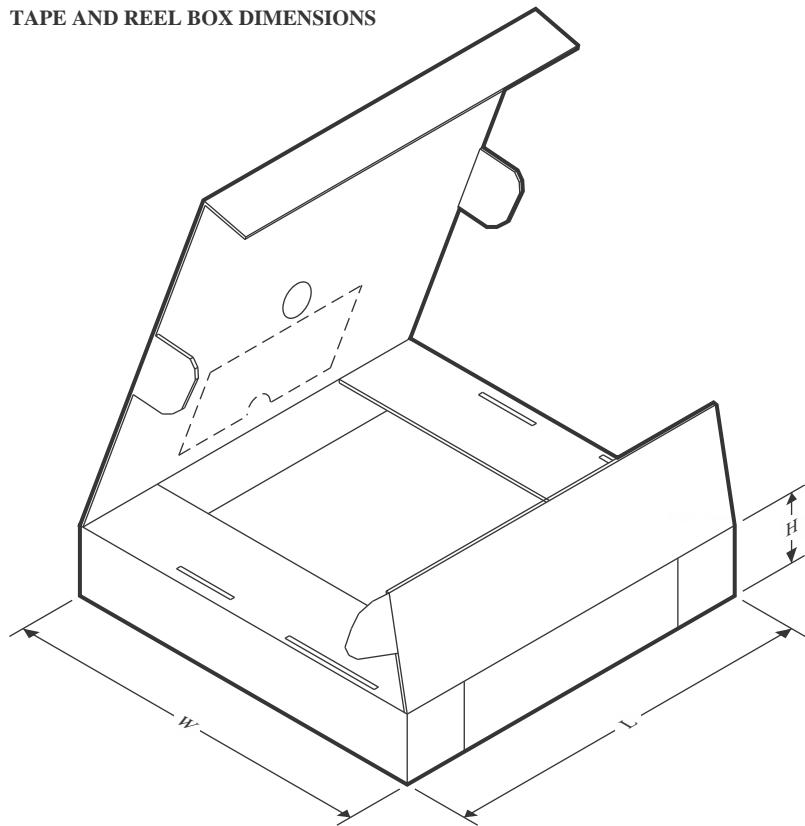
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPSM82810SILR	uSiP	SIL	14	3000	383.0	353.0	58.0
TPSM82810SSILR	uSiP	SIL	14	3000	383.0	353.0	58.0
TPSM82813PVCAR	QFN-FCMOD	VCA	13	2500	367.0	367.0	35.0
TPSM82813SILR	uSiP	SIL	14	3000	383.0	353.0	58.0
TPSM82813SSILR	uSiP	SIL	14	3000	383.0	353.0	58.0

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